



Our chips drive your business

www.lionix-international.com

Integrated Microwave Photonics chip platform using hybrid integration

Robert Grootjans
Design Engineer

October 9th , 2019

Eindhoven, The Netherlands

**LioniX International would like to acknowledge the collaboration with partner Viasat.
This work was funded under ESA contract reference *No. 40000121956/17/NL/CLP***

- ~ Introduction
- ~ Beamforming
- ~ Microwave Photonic link
- ~ Examples
- ~ Experiments/results
- ~ Conclusions
- ~ Future

- ~ LioniX International is a leading global provider of customized microsystem solutions, in particular integrated photonics-based, in scalable production volumes

Why

- ~ Applying disruptive technologies to solve major societal challenges

**Integrated Photonics is
one of the key enablers**



Scalable Production Volumes

The Gallery,
LioniX offices and labs



The Gallery,
Cleanroom, PIC production

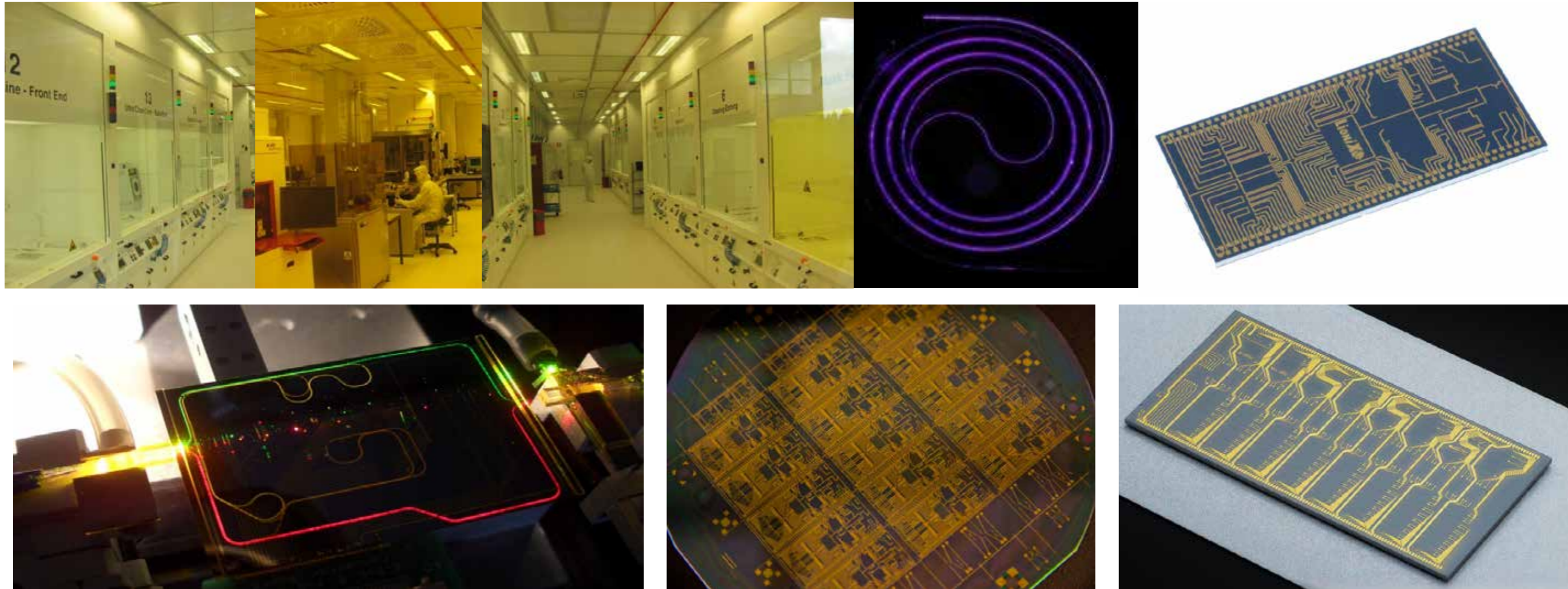


High Tech Factory,
PHIX assembling & packaging Fab

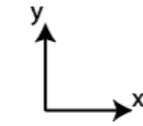
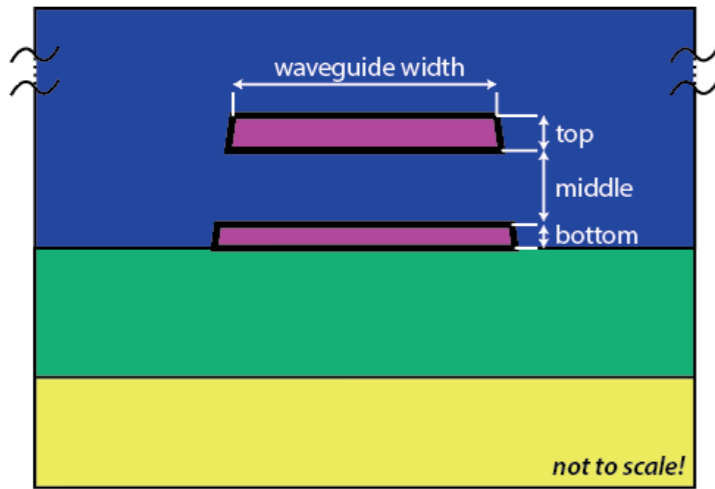


Magic Micro and KANC
Cleanroom, PIC production

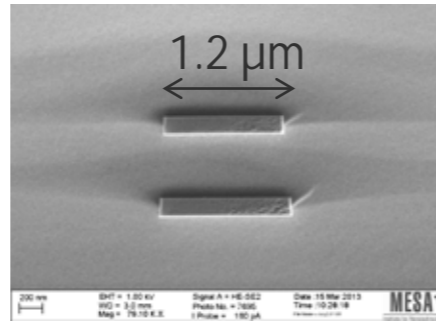




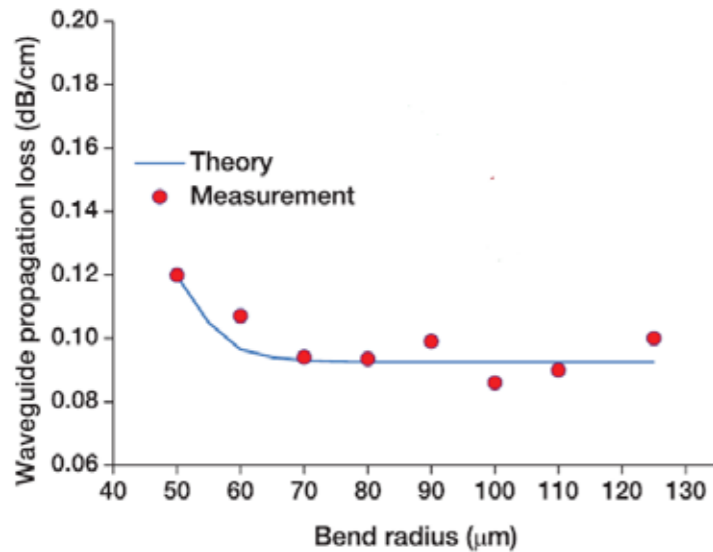
TriPleX Photonic Integrated Chip Platform



- Air
- SiO₂
- Si₃N₄
- Thermal oxide
- Silicium (wafer)

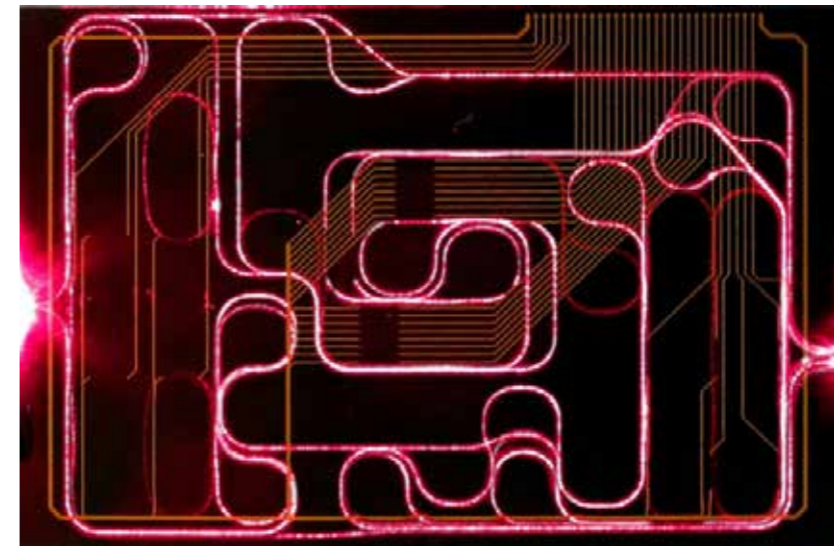


- Low waveguide loss (< 0.1 dB/cm @ 1550 nm)
- Small bend radius (< 80 μm)
- Low loss spot size converters
 - Low coupling loss to single-mode fiber (<0.5 dB)
 - Low chip-to-chip coupling loss (< 1 dB)
- CMOS-compatible fabrication process
- Complex structures
- High optical powers (watts)



L. Zhuang et al., *Optics Express*, 19(23), 23162-23170 (2011)

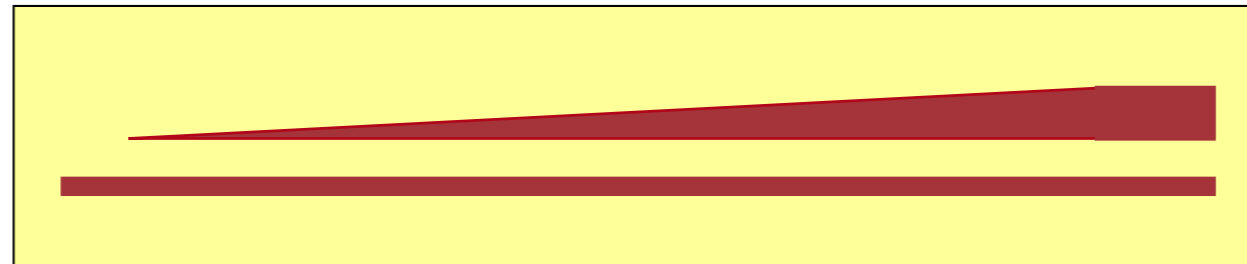
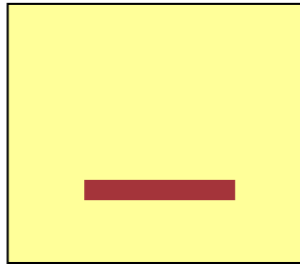
Current review: C. G. H. Roeloffzen et al., *J. Sel. Top. Quant. Elec.*24(4) 1-21 (2018)



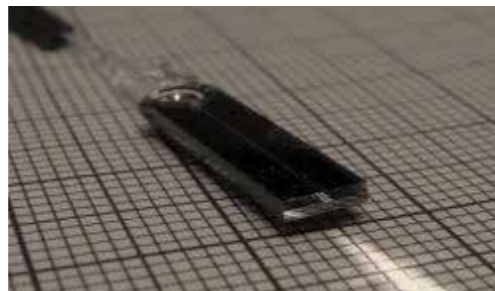
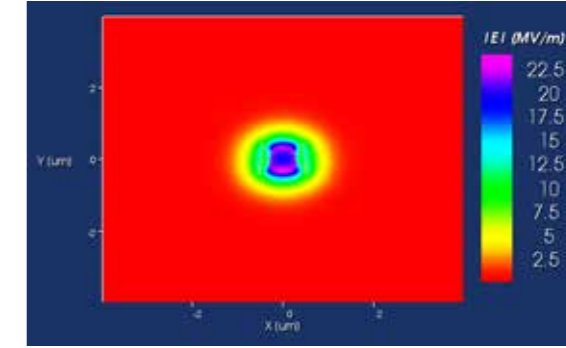
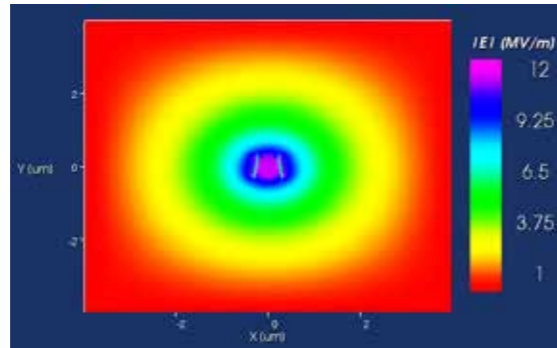
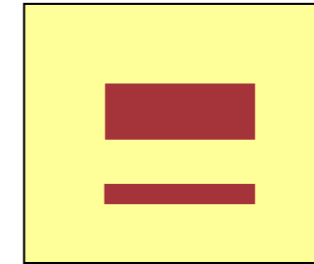
C. Taddei et al., *IEEE MWP 2014, Sapporo, Japan*

Tapering: high \leftrightarrow low index waveguides

Low index contrast



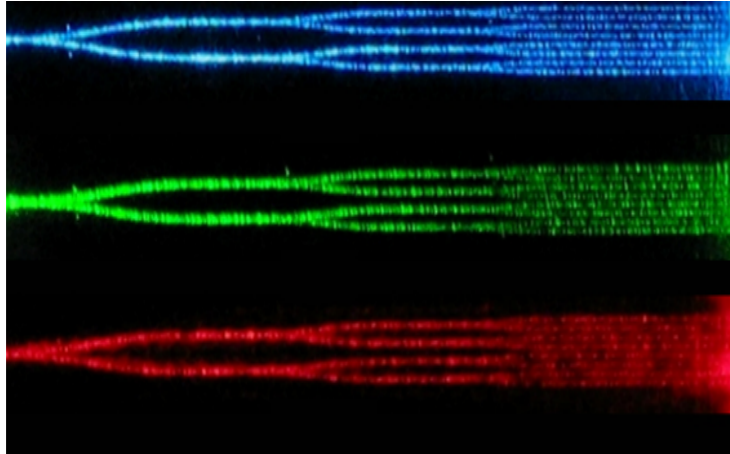
High index contrast



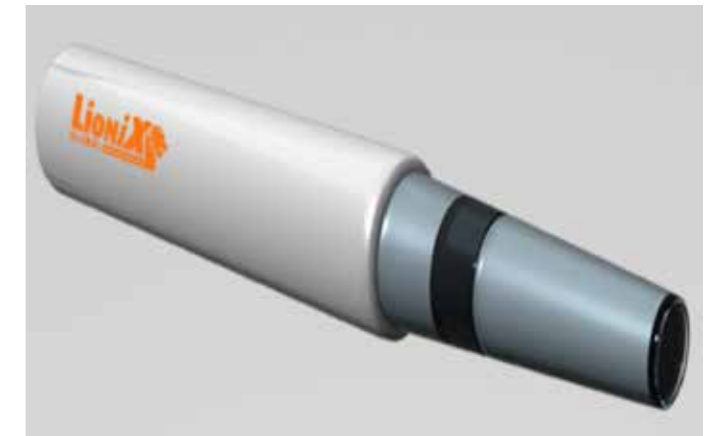
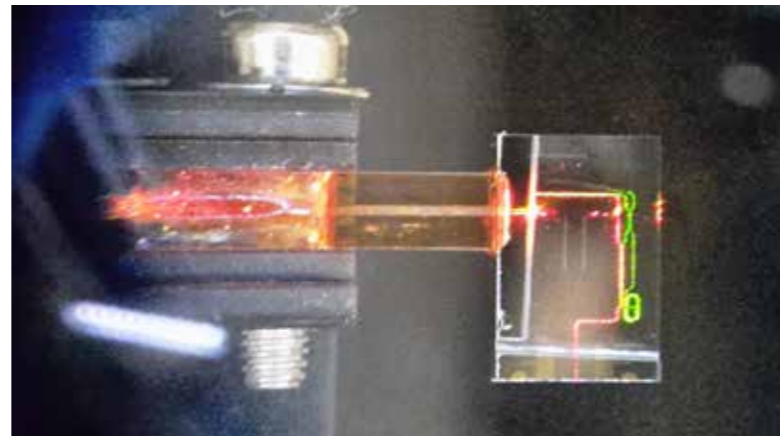
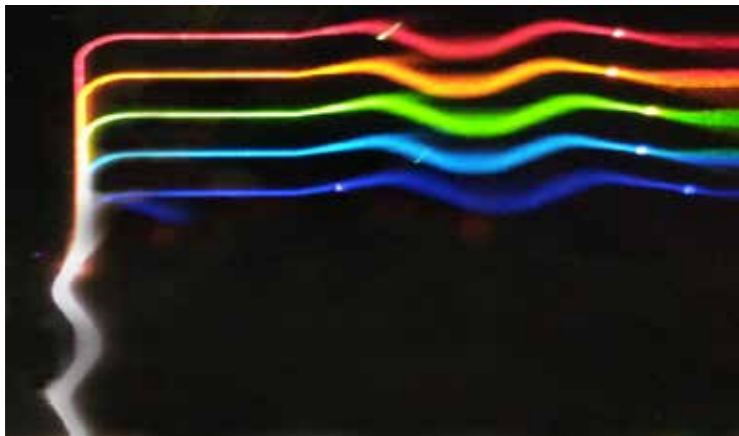
- Mode profiles from 1 μm to > 10 μm
- Modefield conversion
- Pitch conversion
- Low loss coupling to almost any external component, including SM fiber, InP and Si (SOI)

Basic examples

Wide-band power splitters

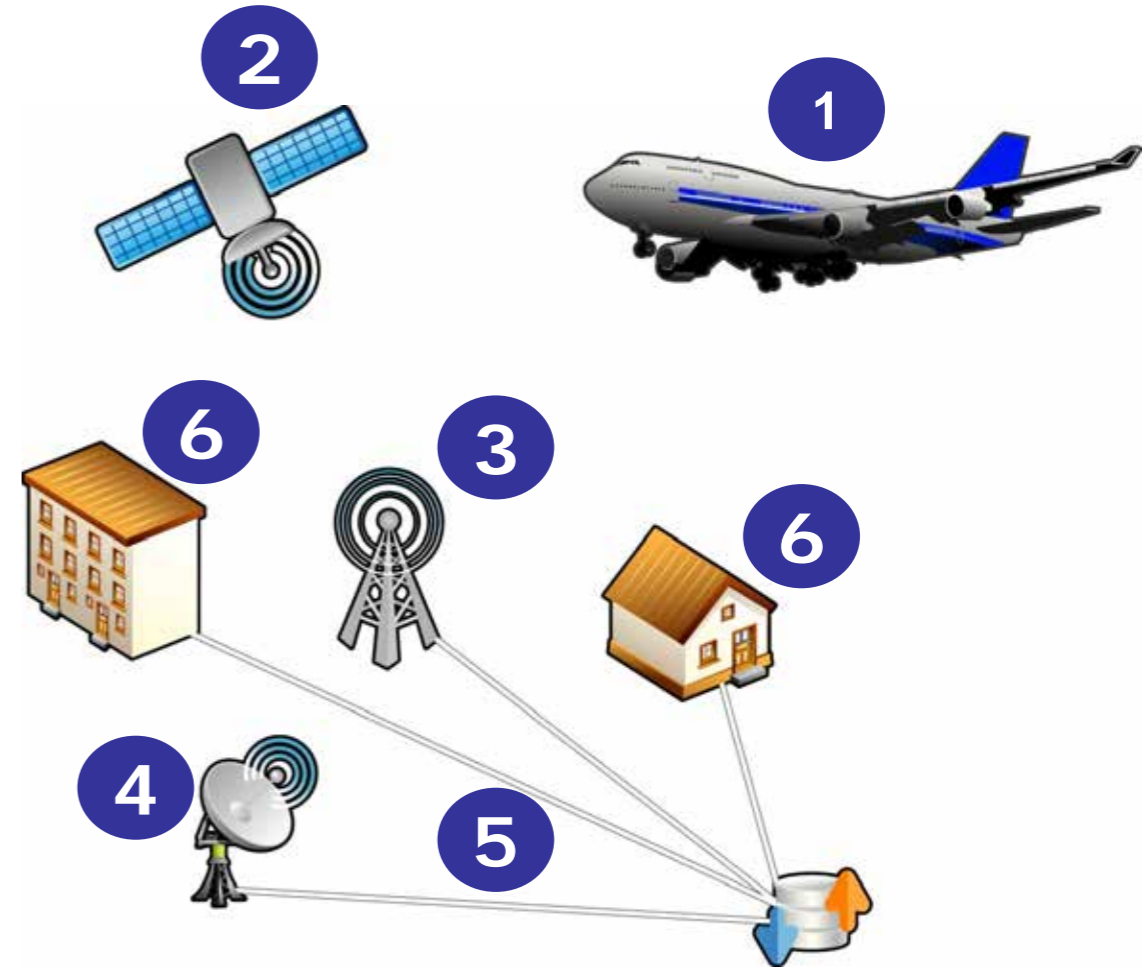


wide-band spectrometers, interferometers

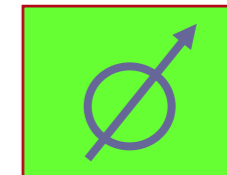
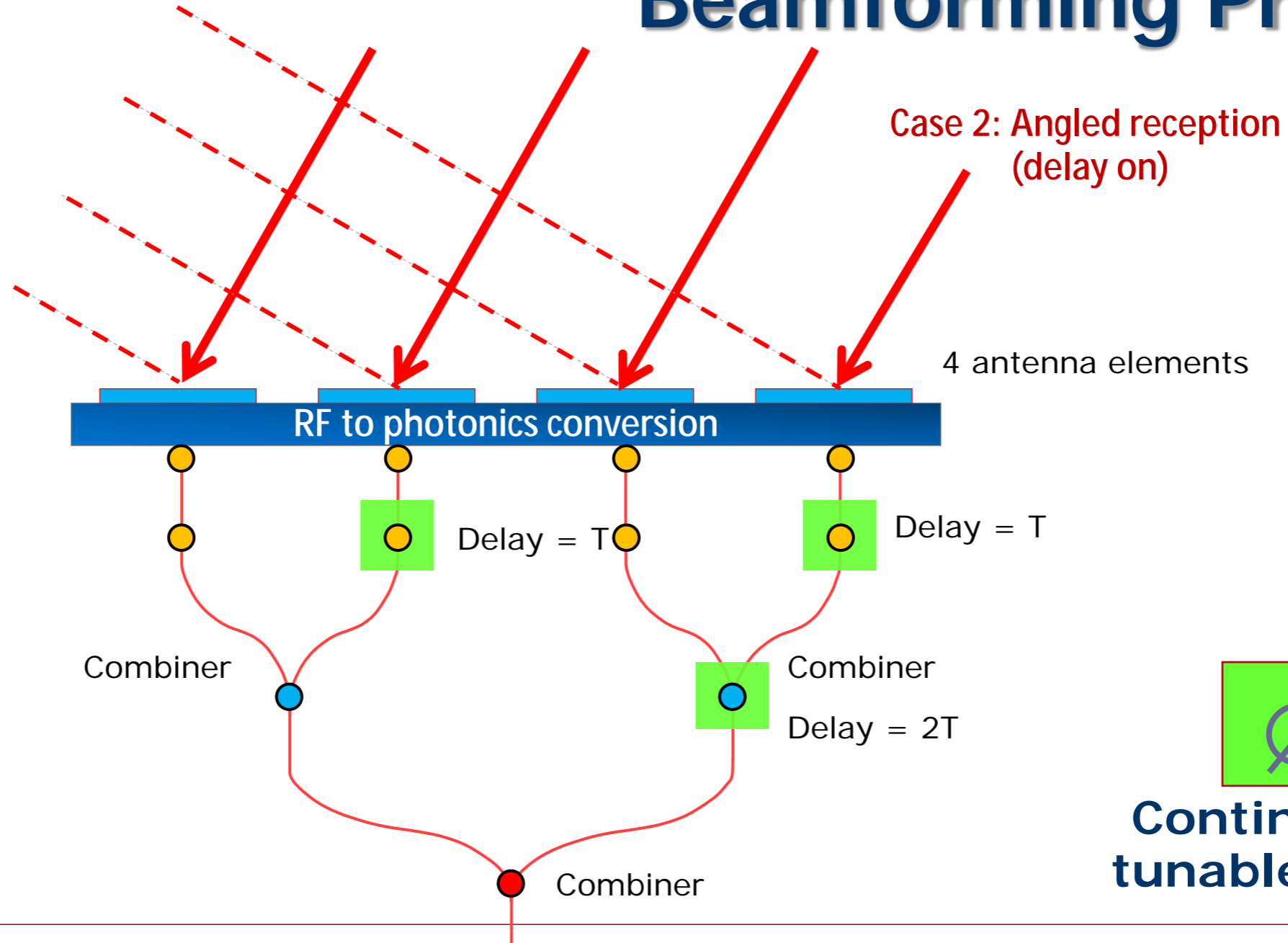


Opportunities

1. Satellite communication terminals on high speed vehicles
2. Satellite communication terminals on GEO or LO satellite
3. Directional antennas for 5G Infrastructure
4. Beam forming modules for astronomy
5. High Dynamic Range photonic link
6. High Speed Indoor solution (60 GHz)

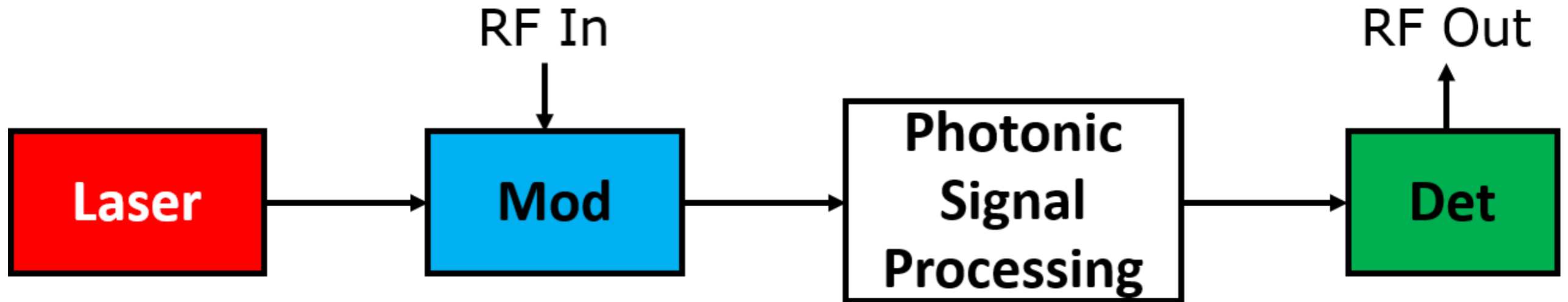


Beamforming Principle



Continuously tunable delays

Microwave Photonic Link



Analog Photonic Link

$$G_{PM_SSBFC} = \frac{P_{RF_out}(t)}{P_{RF_in}(t)} = \left(\frac{\pi R_{pd} P_l R}{2LV_{\pi}} \right)^2 = \left(\frac{\pi I_{pd_DC} R}{2V_{\pi}} \right)^2$$

$$I_{pd_DC}(t) = R_{pd} \frac{P_l}{L}$$

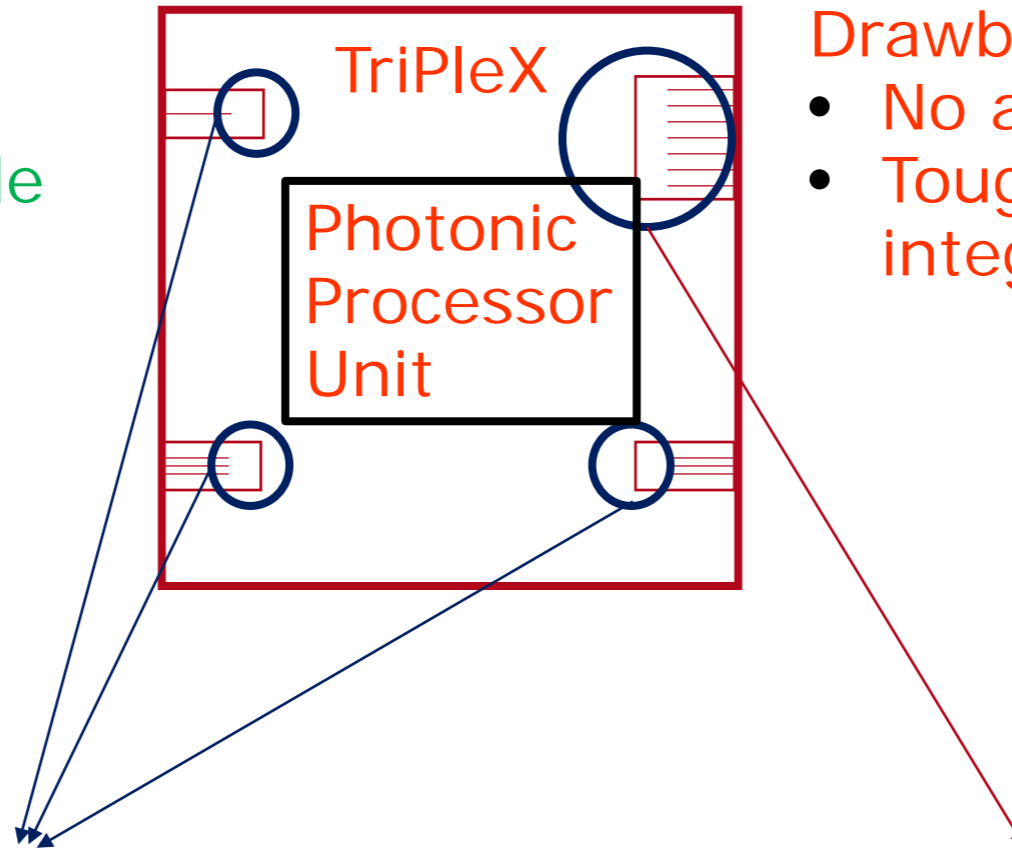
P_l = Laser power (50 mW)
 V

- ~ Low optical propagation loss
- ~ High performance active components
- ~ Efficient Electrical to optical conversion
- ~ Powerful lasers
- ~ High power handling
- ~ Robust processing/assembly

TriPleX Photonic Signal Processing

Strengths:

- Low loss
- Long distances possible
- Small bend radius
- Spot size converters
- Easy process
- Robust
- Capable of handling high powers



Drawbacks:

- No active components
- Tough to monolithically integrate with other platforms

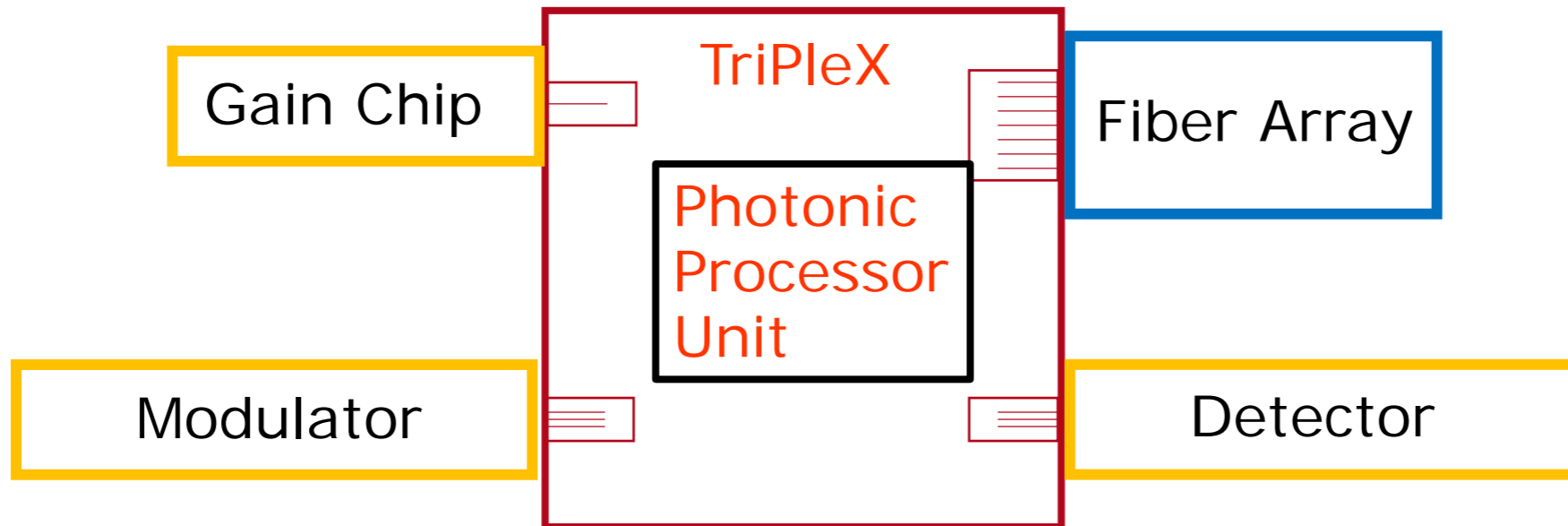
Interfaces to Indium Phosfide (InP)

Interface to PM SM fiber

- ~ Low optical propagation loss through the whole optical path
- ~ High performance active components
- ~ Efficient Electrical to optical conversion
- ~ Powerful lasers
- ~ High power handling
- ~ Robust processing/assembly

- ~ Low optical propagation loss through the whole optical path
- ~ High performance active components
- ~ Efficient Electrical to optical conversion
- ~ Powerful lasers
- ~ High power handling
- ~ Robust processing/assembly

- ~ Combine the best of two platform In this case TriPleX and InP



- ~ Low optical propagation loss through the whole optical path
- ~ High performance active components
- ~ Efficient Electrical to optical conversion
- ~ Powerful lasers
- ~ High power handling
- ~ Robust processing/assembly

- ~ More difficult than monolithic processing

~ Multiple Indium Phosphide Chips

~ Laser

- High power laser (> 50 mW)
- High power gain (> 100 mW)
- Small linewidth (< 10 kHz)

~ Modulator

- High speed (> 40 GHz)
- Sensitive ($V < 3$ V)

~ Detectors

- High speed (> 40 GHz)
- Responsivity (> 0.6 A/W)

~ Very low RF crosstalk required (< -70 dB)

~ TriPLeX, Silicon Nitride chips

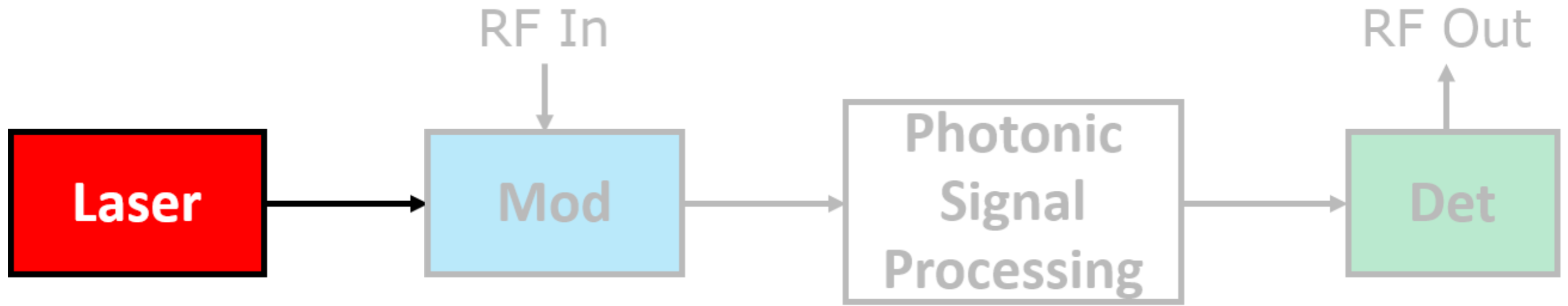
~ High contrast, low loss optical processing

~ Spot size converters for low loss interfacing

~ High integration density +

~ Efficient, low-power tunability

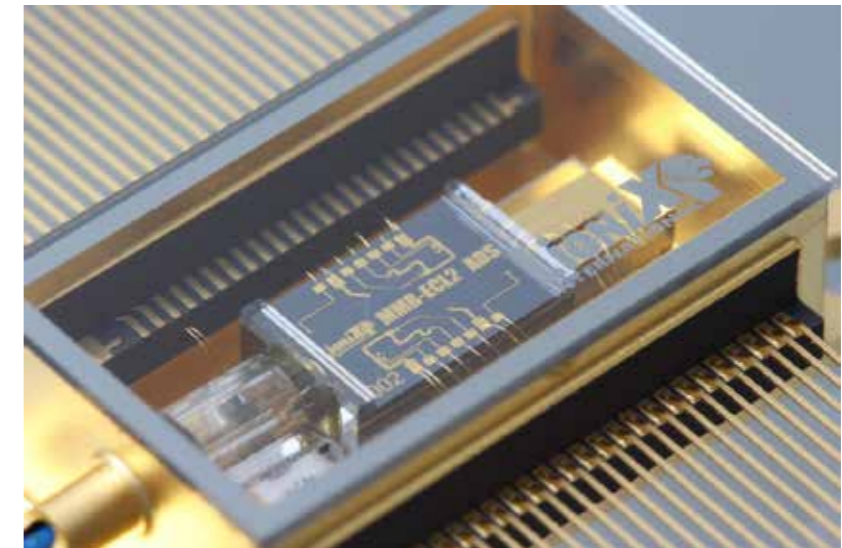
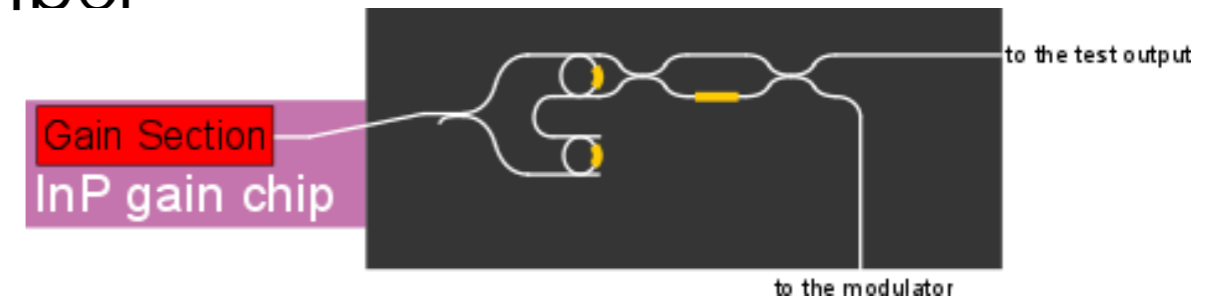
~ Drives Co\$t Down



Tunable hybrid integrated laser source

- ü High optical power (**>50 mW**), small bandwidth (several kHz, **sub-kHz**)
- ü Mode matched to standard telecom fiber
- ü High side mode suppression
- ü Tunable over C-band (**>80 nm**)
- ü Potential to integrate other optical functions on TriPleX chip

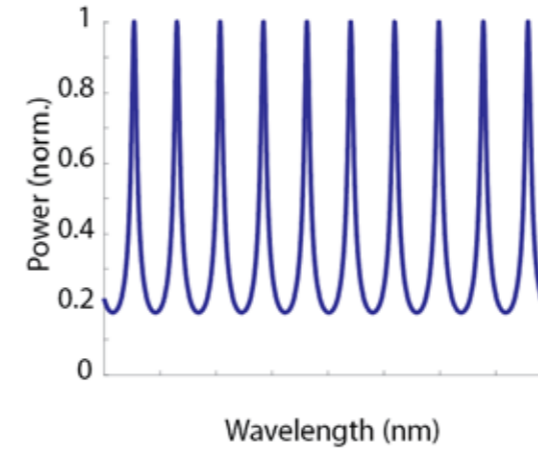
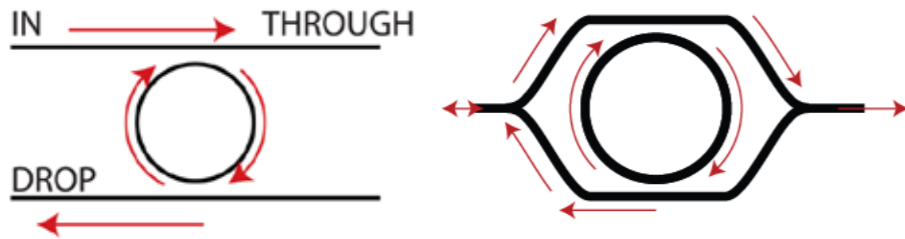
- ü **Recent record performance**



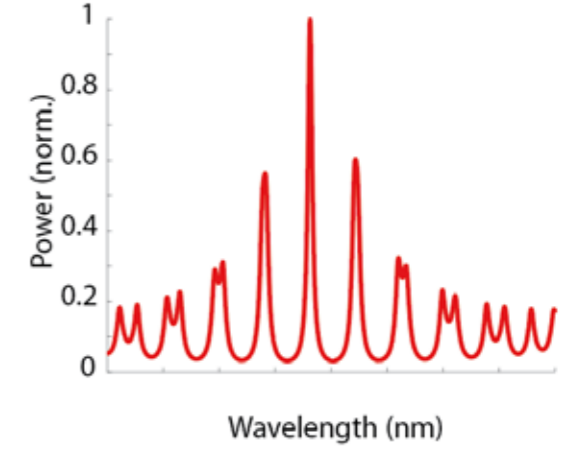
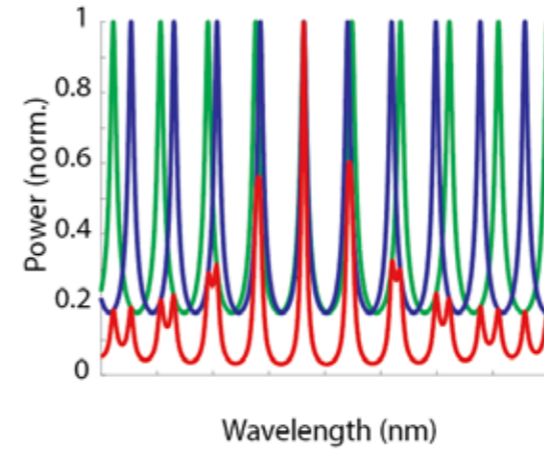
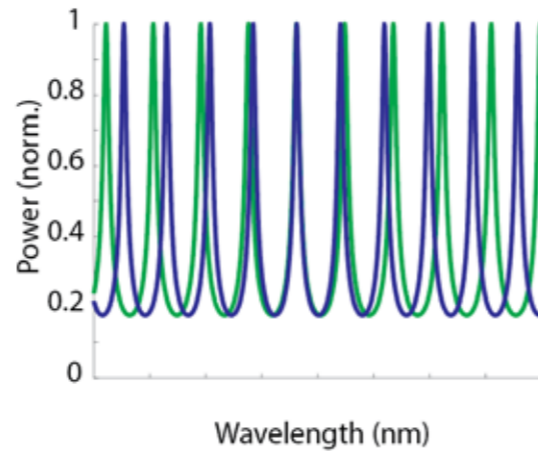
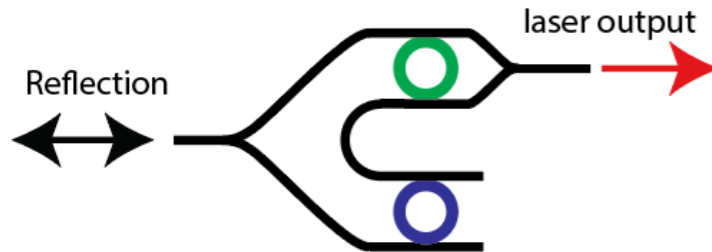
Oldenbeuving, et al., Laser Phys. Lett. 10 (2013) 015804
Fan, et al., CLEO 2017.

Laser working principle

~ Single ring reflector



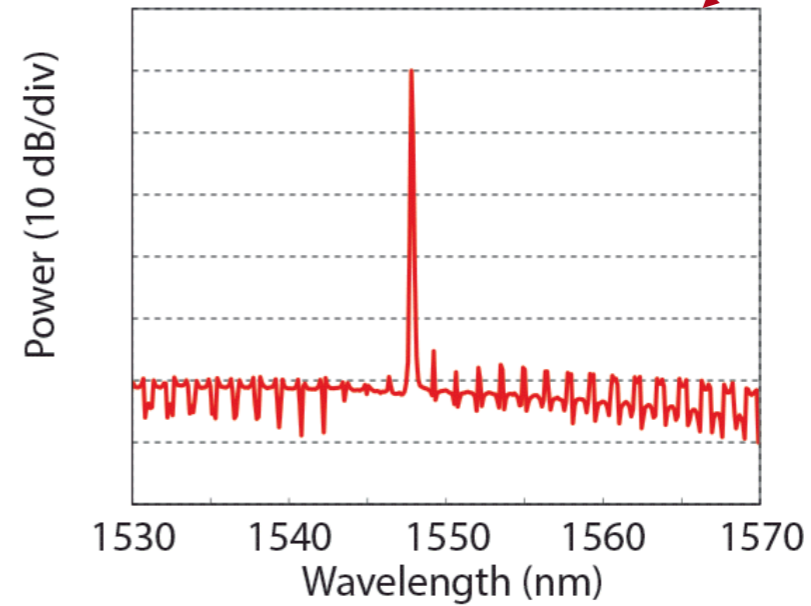
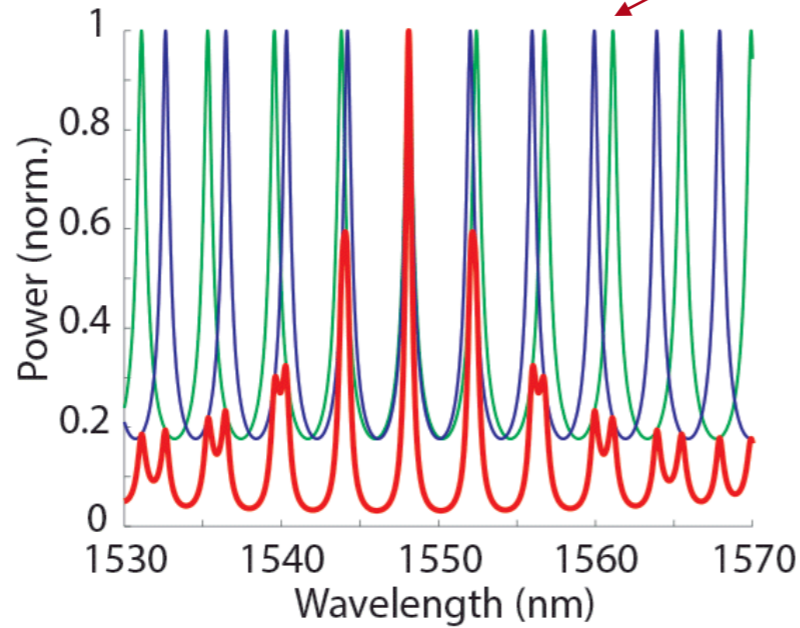
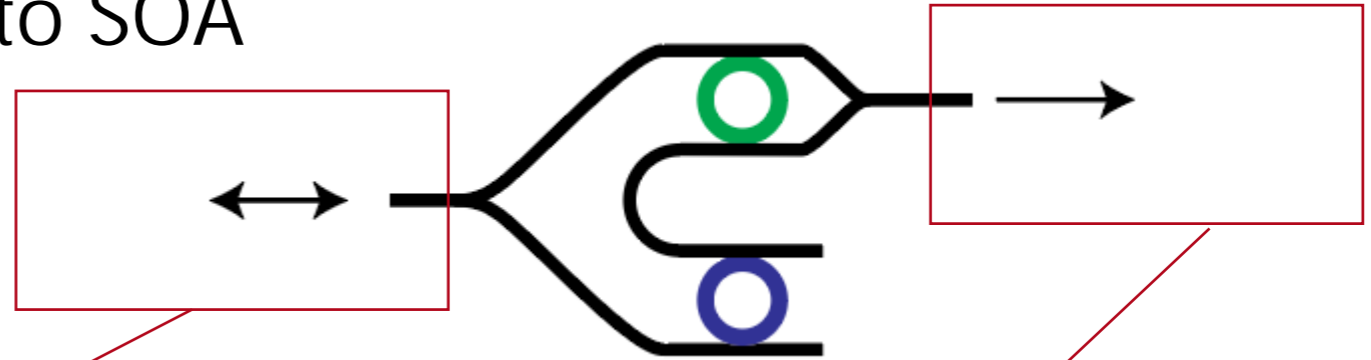
~ Double ring reflector



Simplified explanation

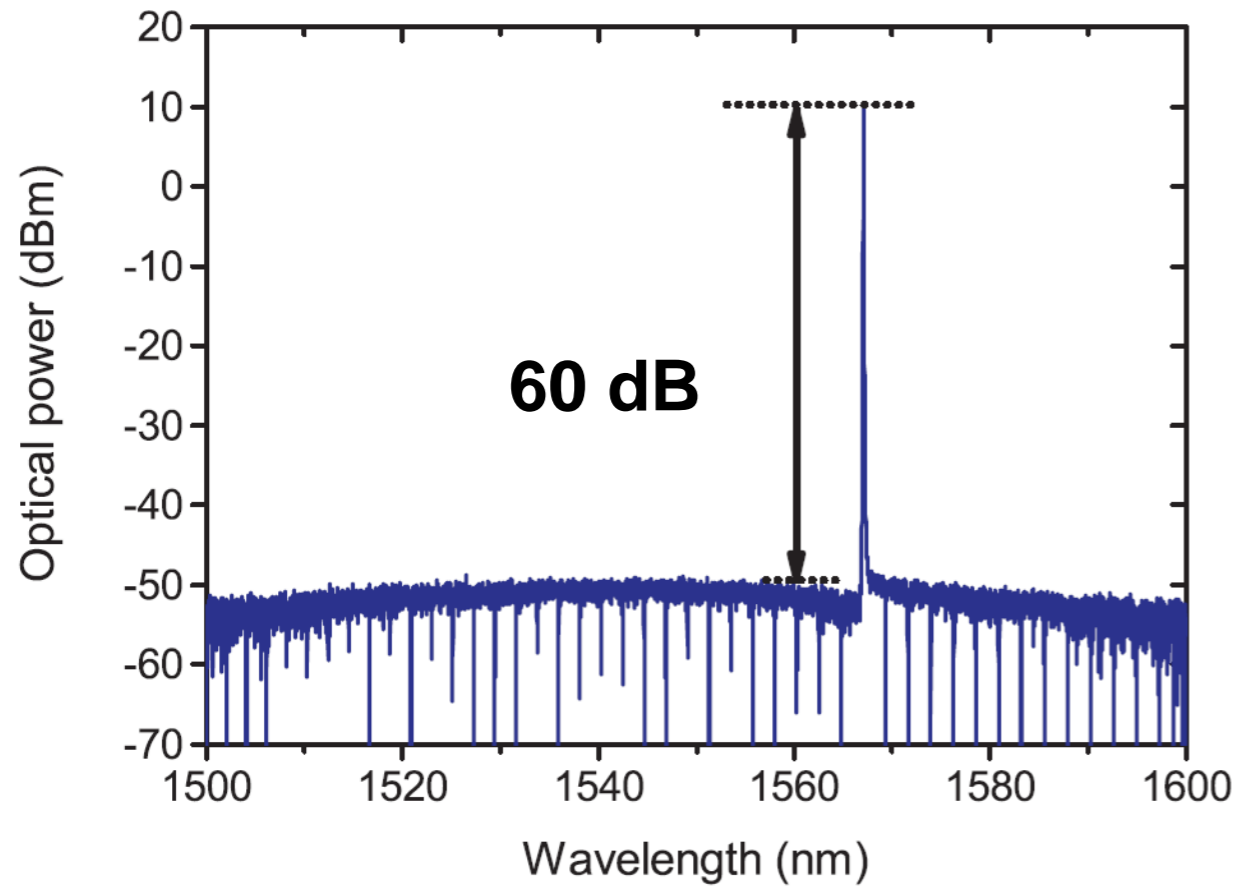
~ Double ring reflector, attach to SOA

Heating 1 ring
Causes spectrum
to hop across
wavelengths

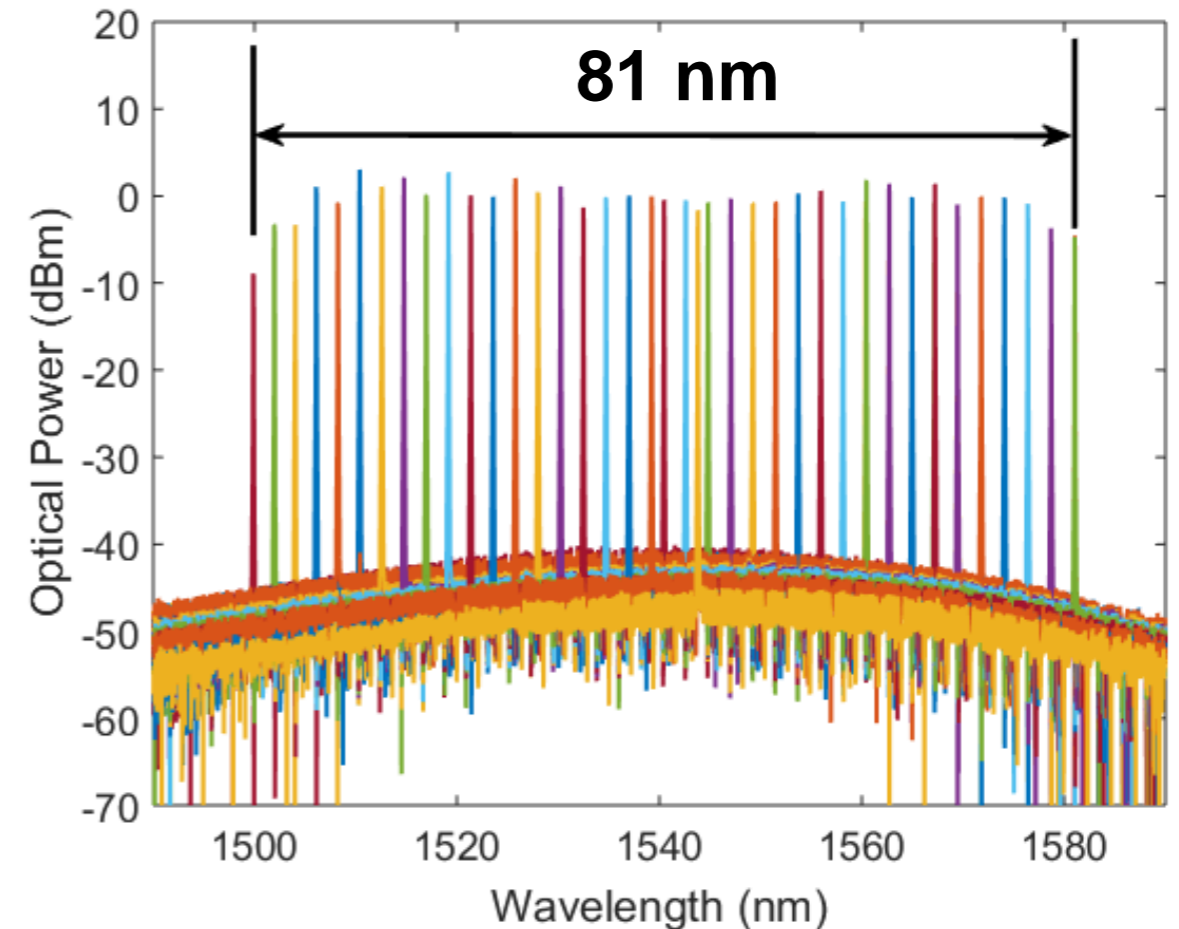


Hybrid Laser Spectral characterization

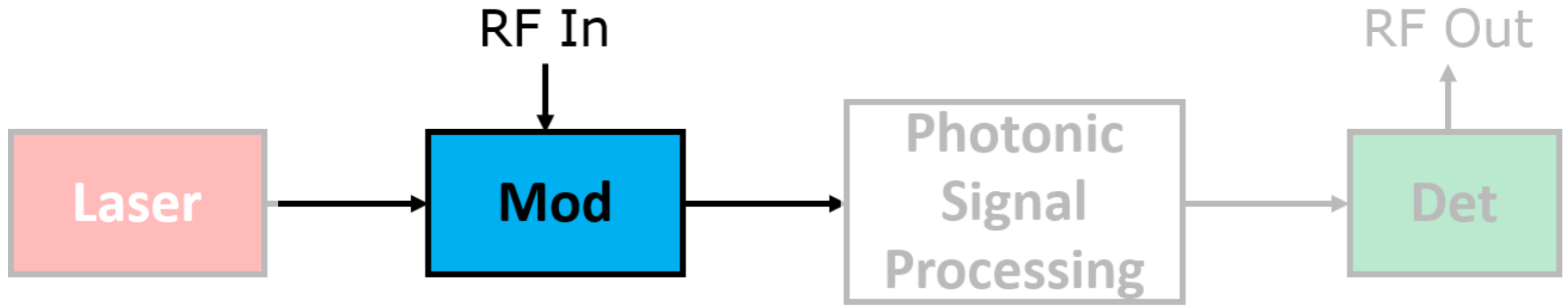
Single frequency output



Wide tuning range

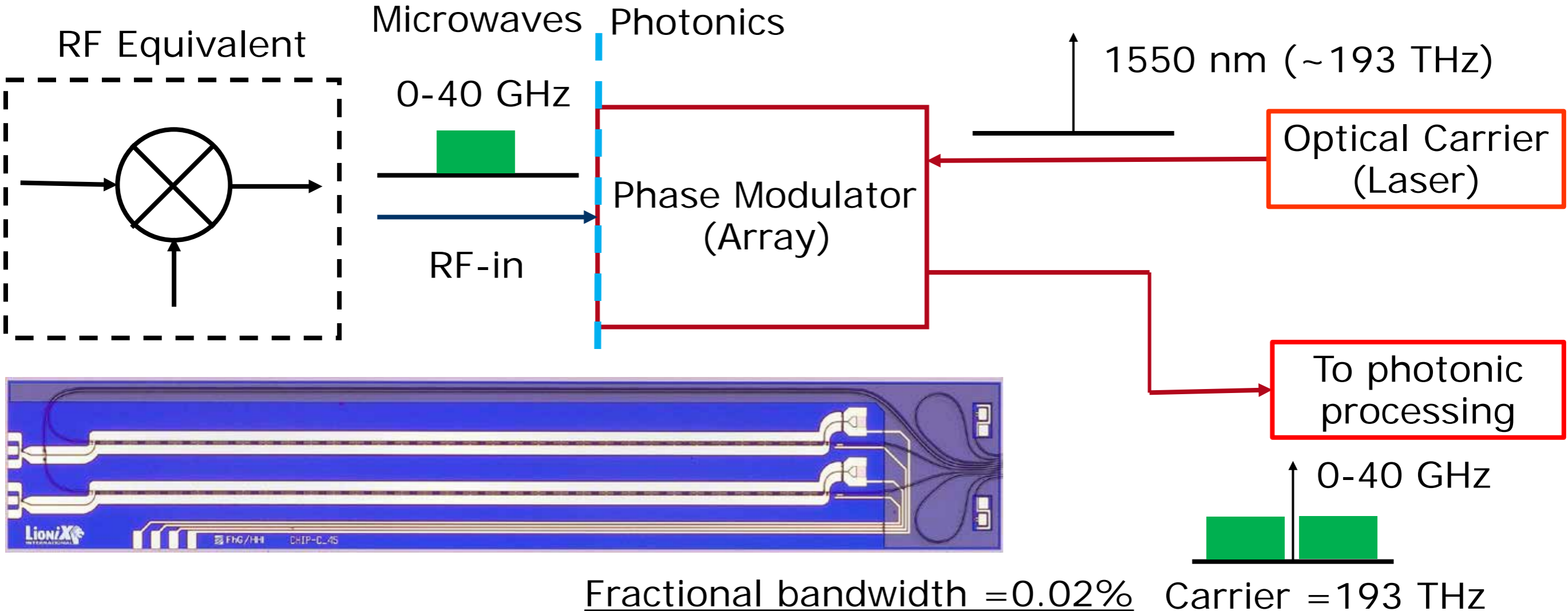


MPL: Phase modulator

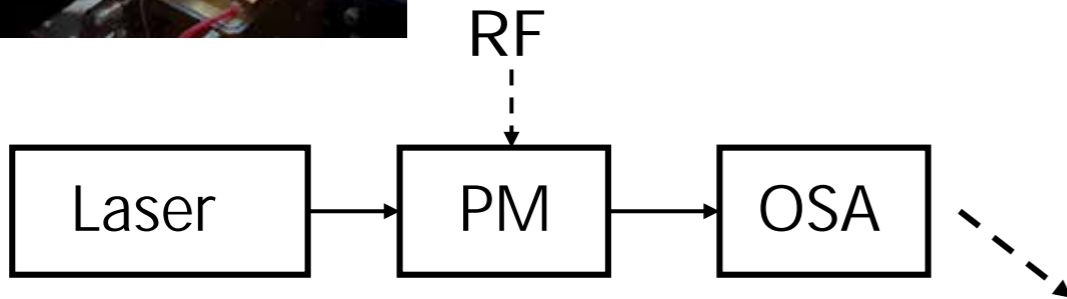


Modulator Functionality

Convert an analog microwave signal to an optically modulated signal



InP Modulator (E/O conversion)

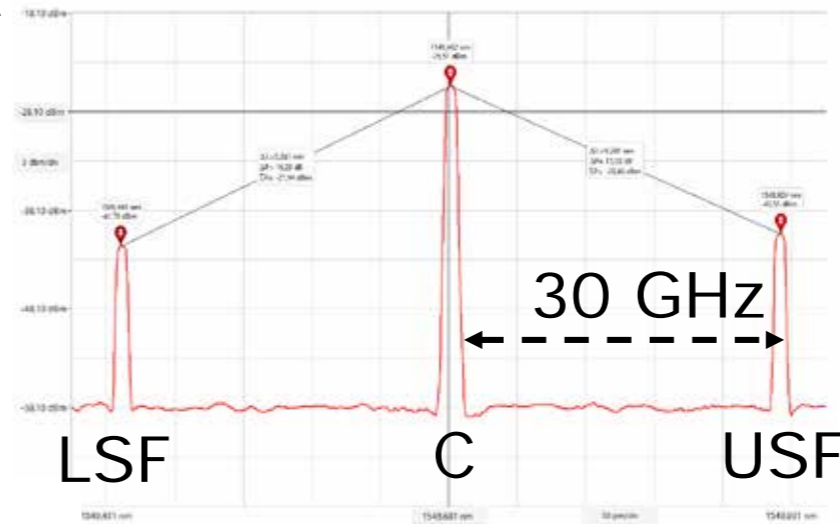


Freq (GHz)	(dB)	m	V (V)
5	10.2	0.5907	1.68
10	10.9	0.5485	1.80
20	13.2	0.4275	2.30
30	15.6	0.3275	3.00

Increase RF power until sidebands are as high as the carrier.

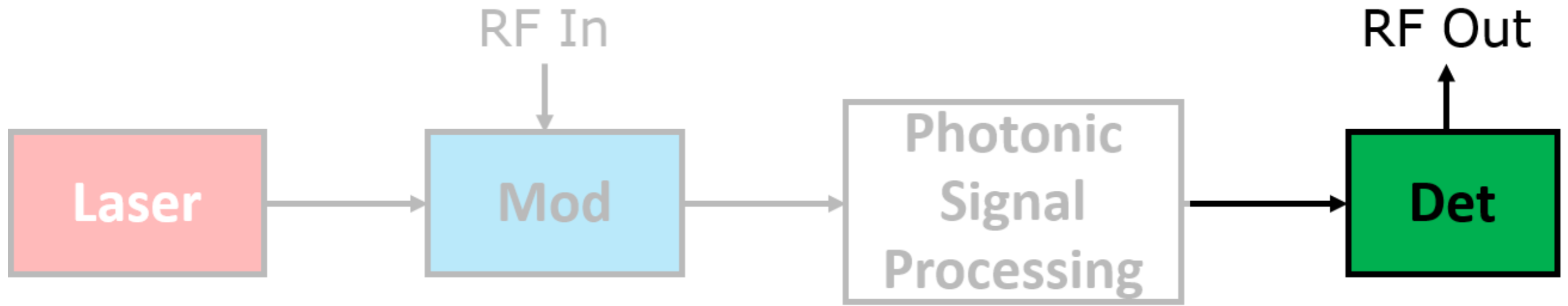
Calculate using: $V_{\pi} = \frac{V_m}{0.457}$

Where: $V_m = \sqrt{2P_{RF}R}$

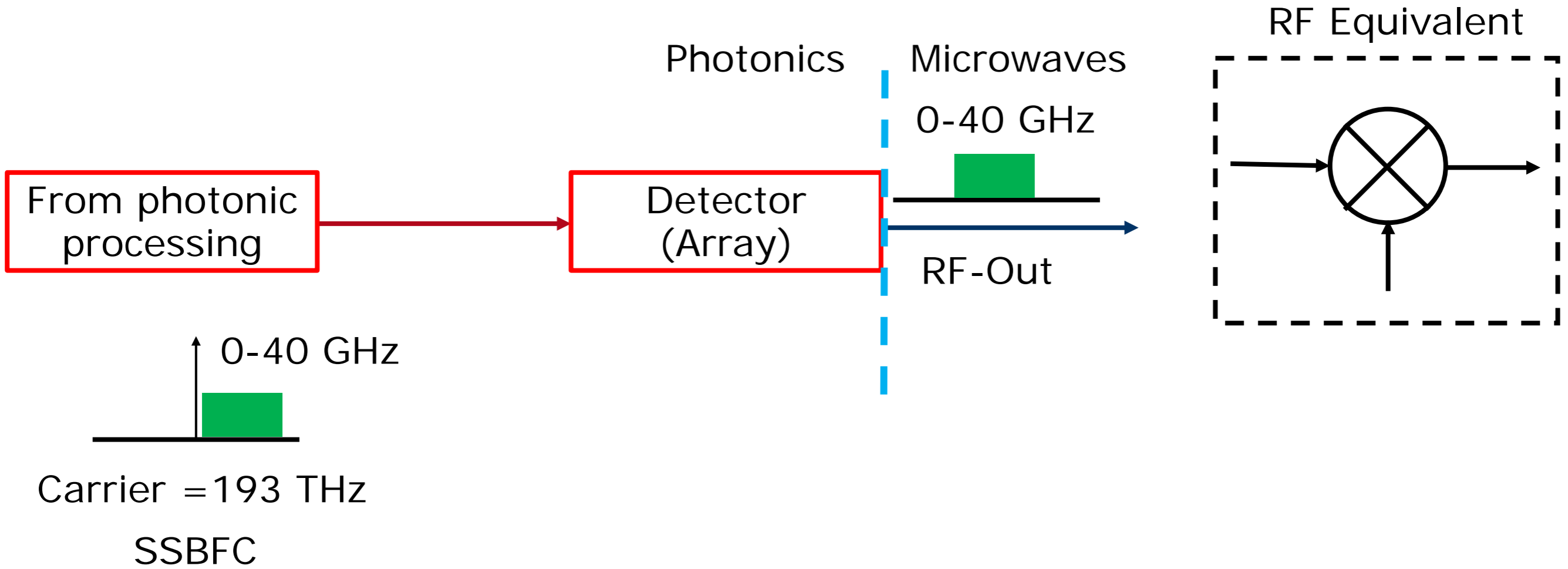


↑
VERY GOOD !

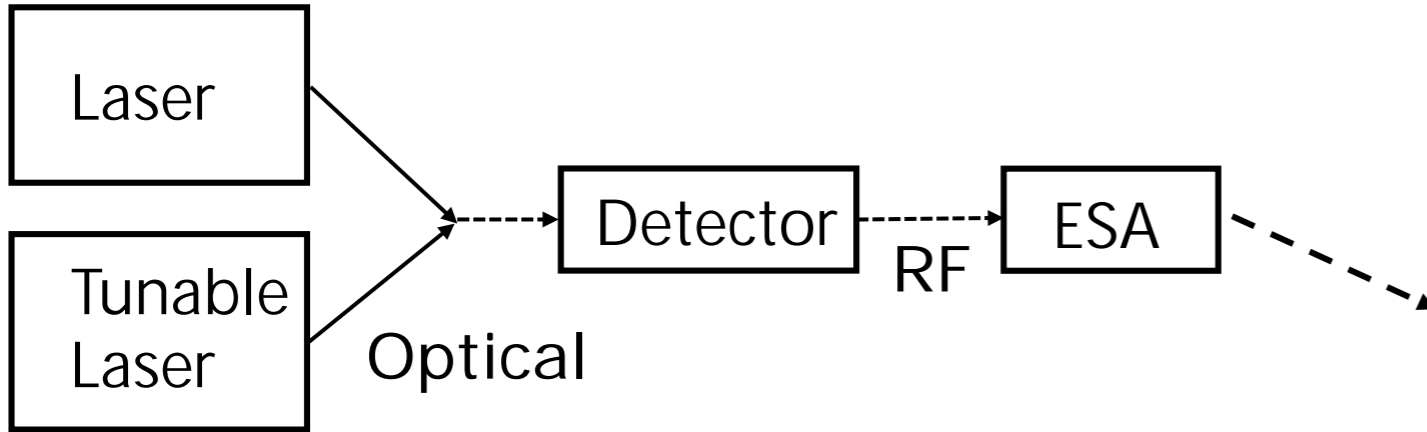
Optical spectrum analysis method (Yongqiang Shi et al., IEEE JLT 21 (10), 2003)



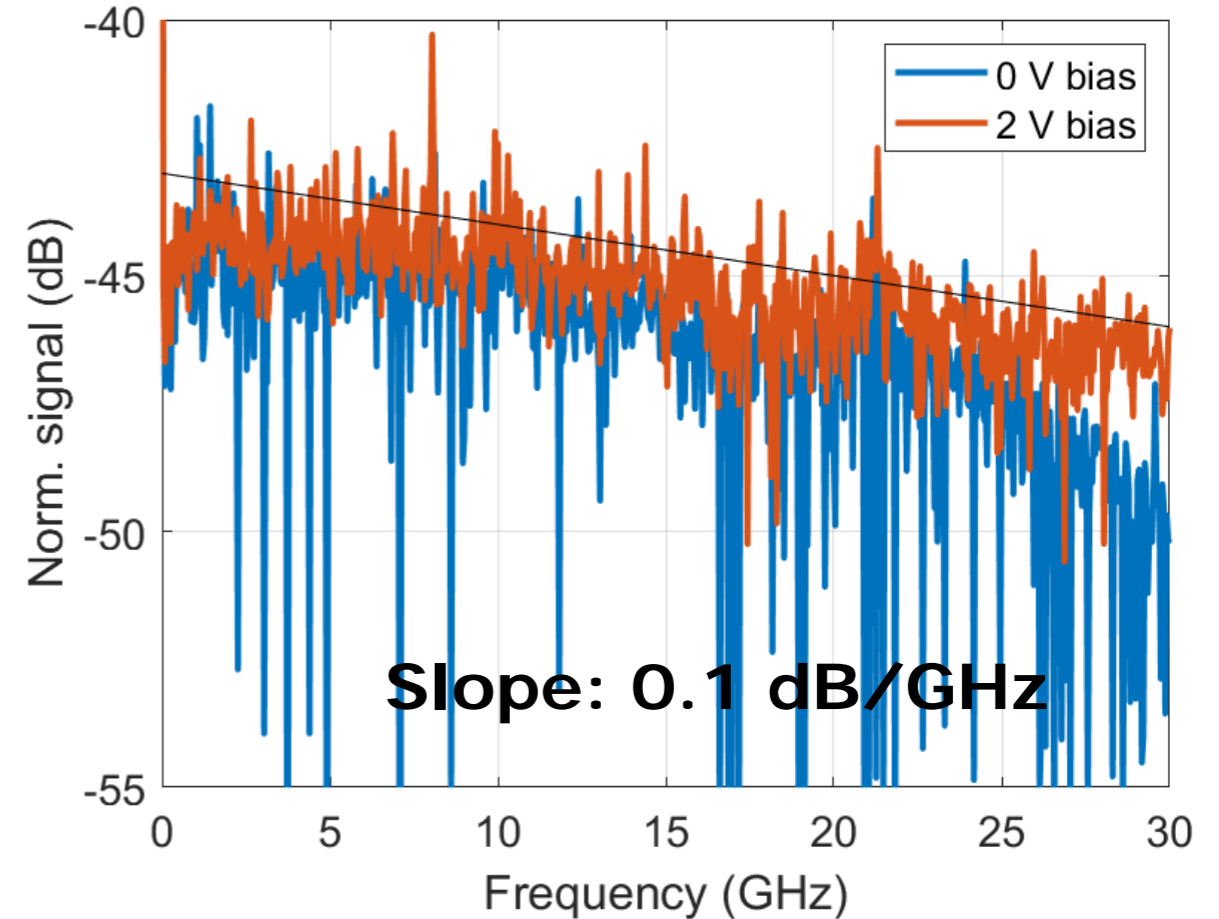
Detector functionality



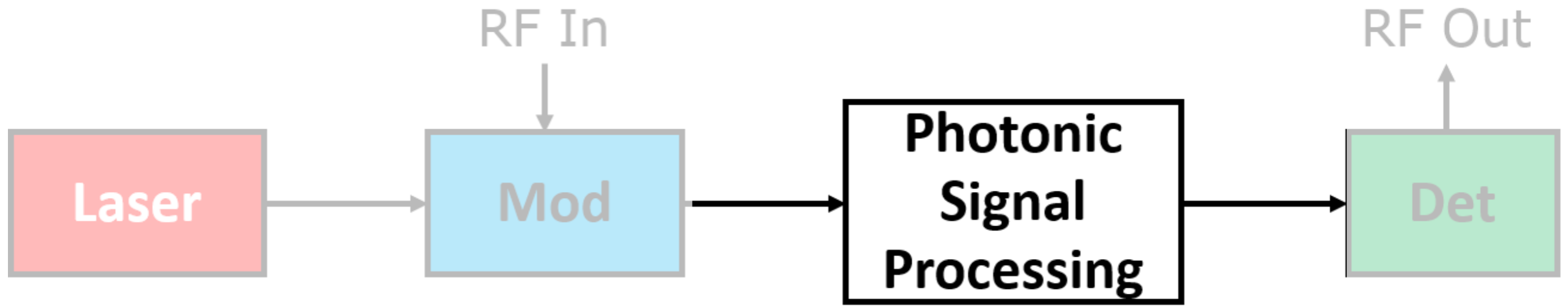
Detector responsivity/slope



- ü High speed: > 40 GHz
- ü Responsivity > 0.5 A/W
- ü Internal Matching and biasing network

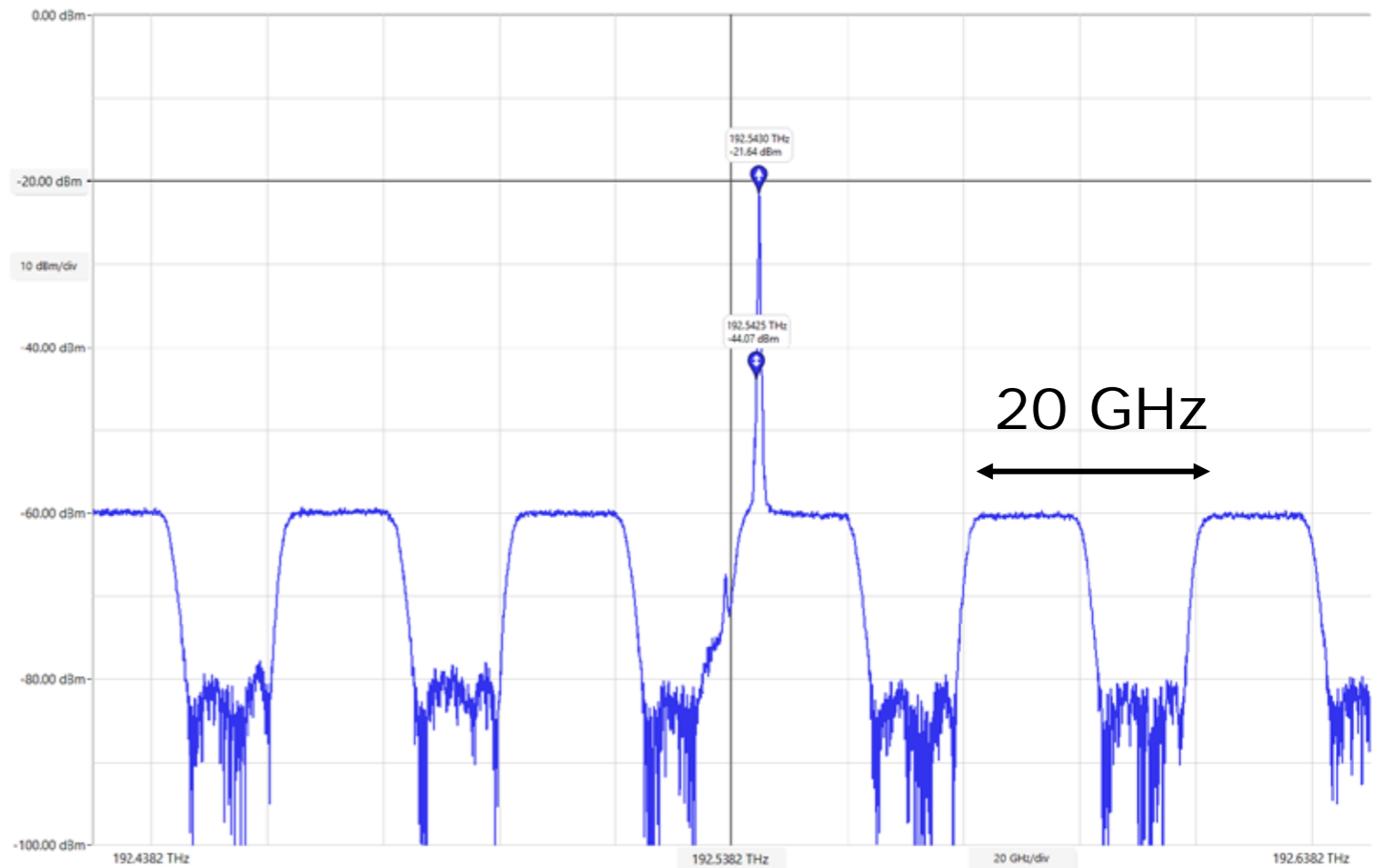


MPL: Signal processing

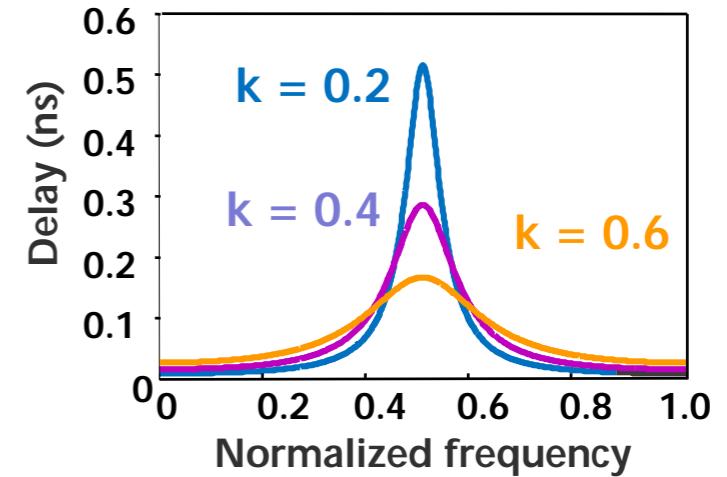
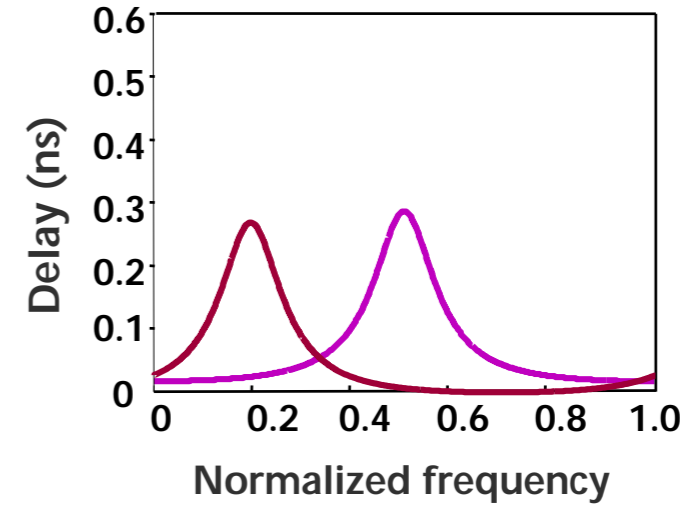
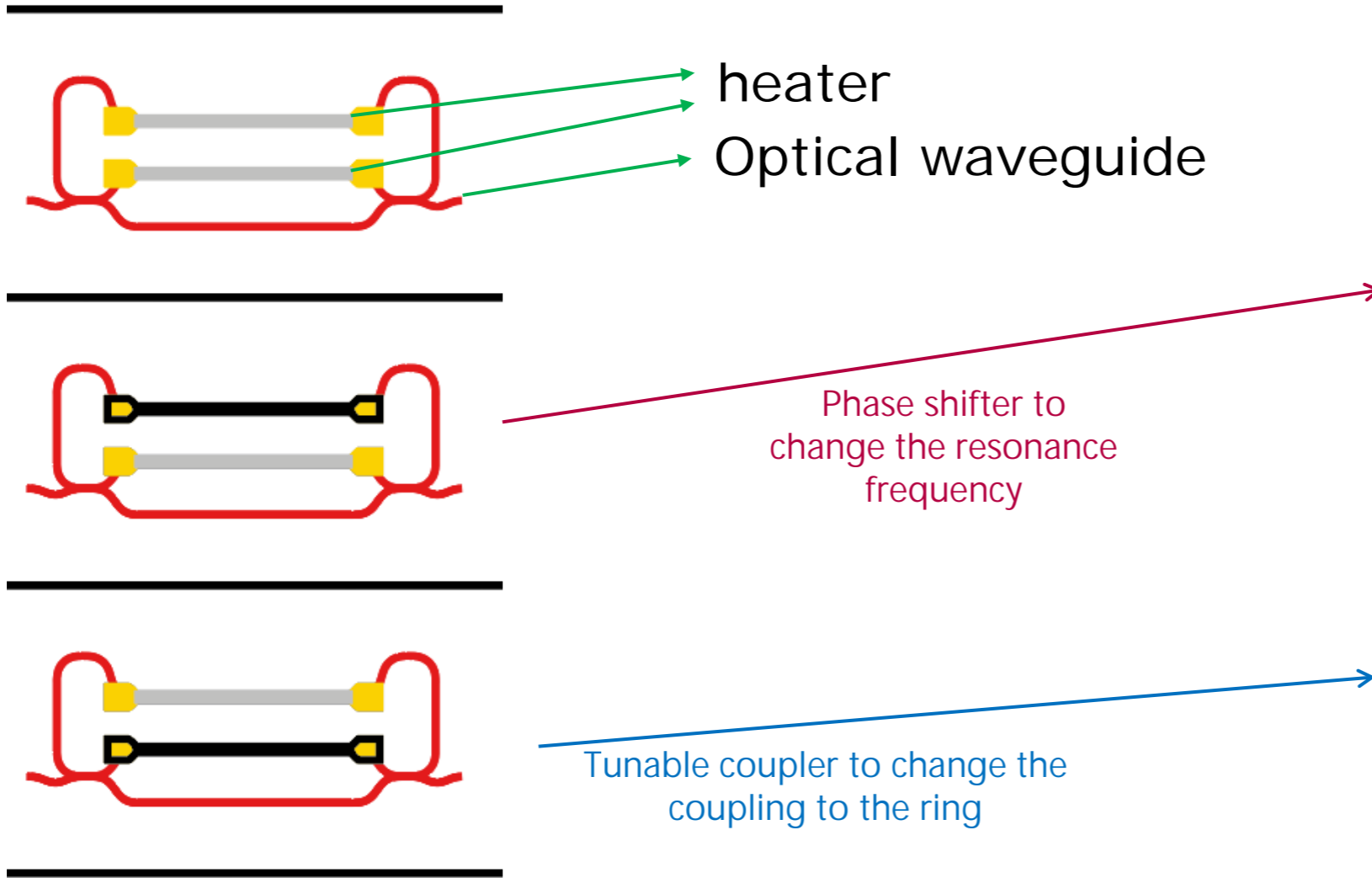


TriPleX- Filter for SSBFC processing

- ~ Flat filter response
- ~ Passband loss < 0.2 dB
- ~ > 20 dB stopband rejection
- ~ Carrier in the passband
- ~ USB in the passband
- ~ LSB in the stopband

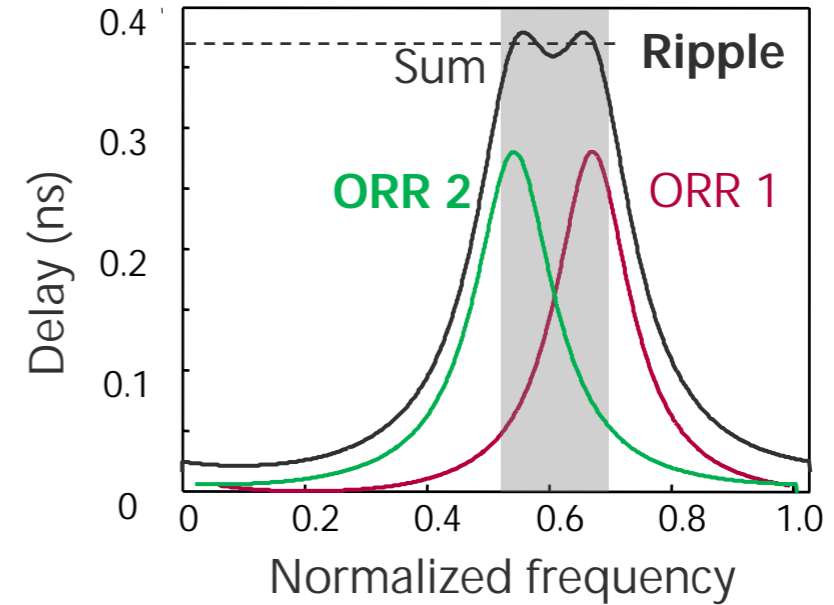
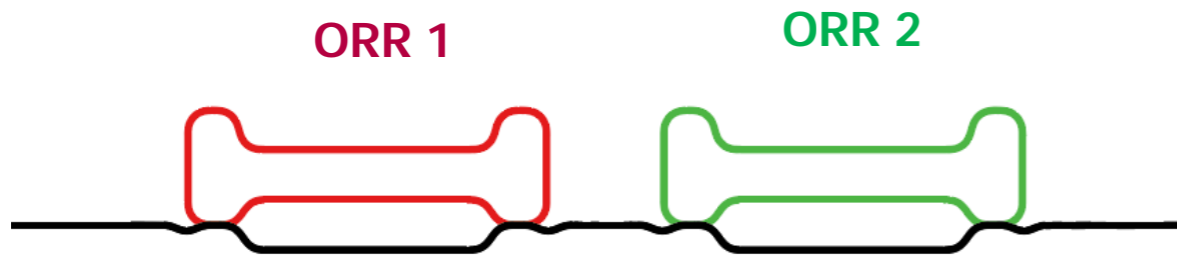


True time delay via optical ring resonator



Cascaded optical ring resonators

- Single ORR provides tunable delay, but it is band limited
- Trade-off between maximum delay and delay bandwidth
- Solution → cascade more than one ORRs

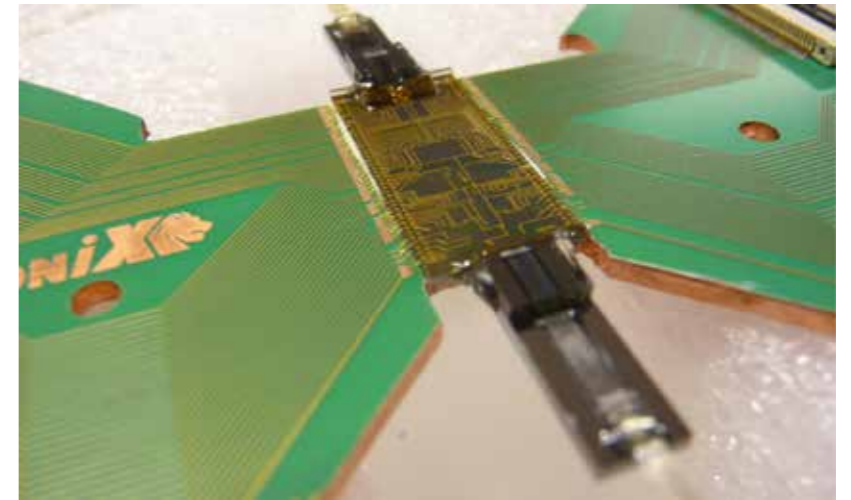
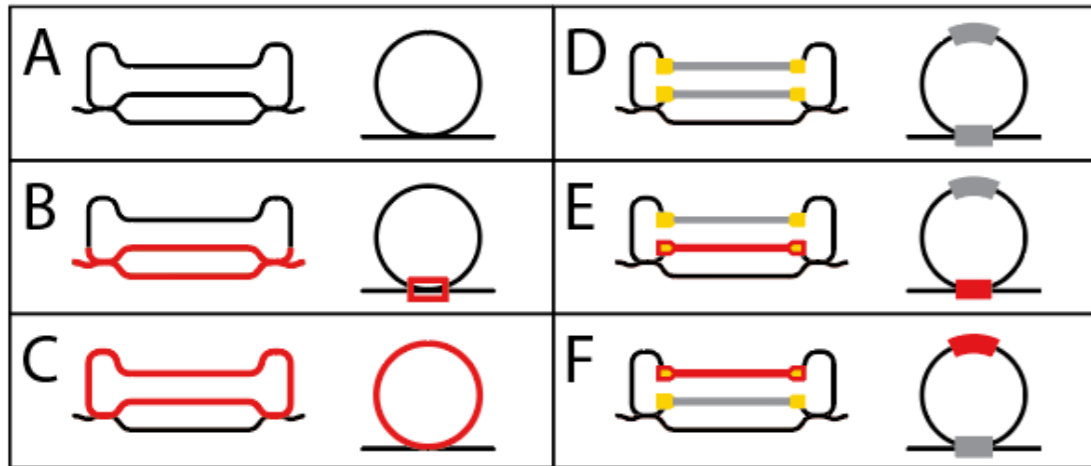
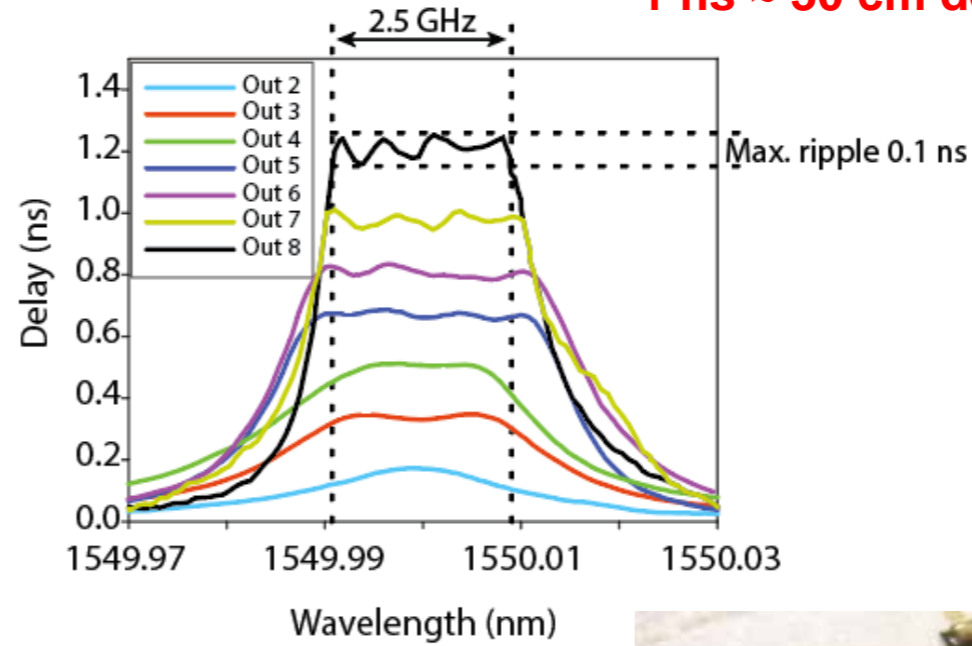
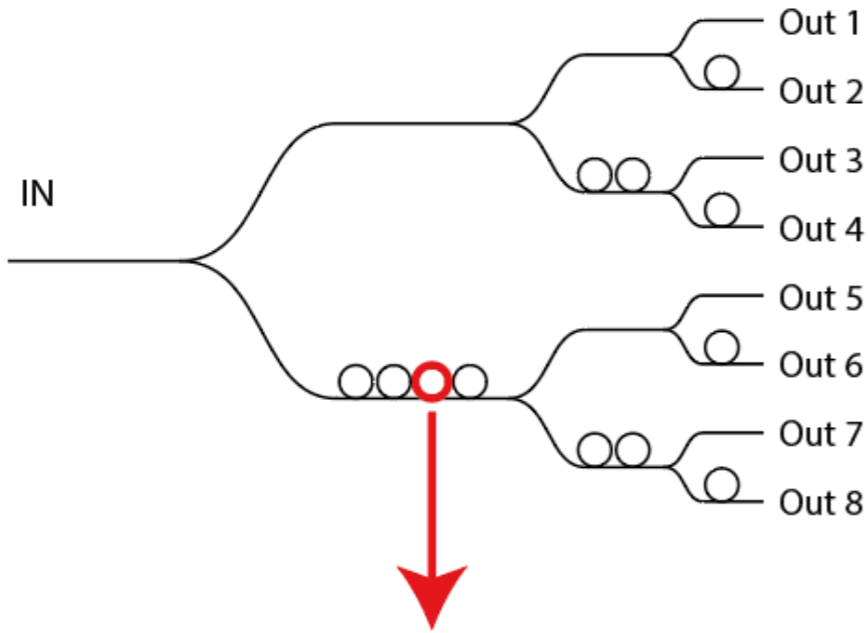


- More ORRs cascaded → more bandwidth but more ripple
- Trade-off between bandwidth, the number of ORR and the delay ripple

Next step: to arrange the combiners and the ORRs or spirals to make a beamformer

Binary tree optical beamforming network

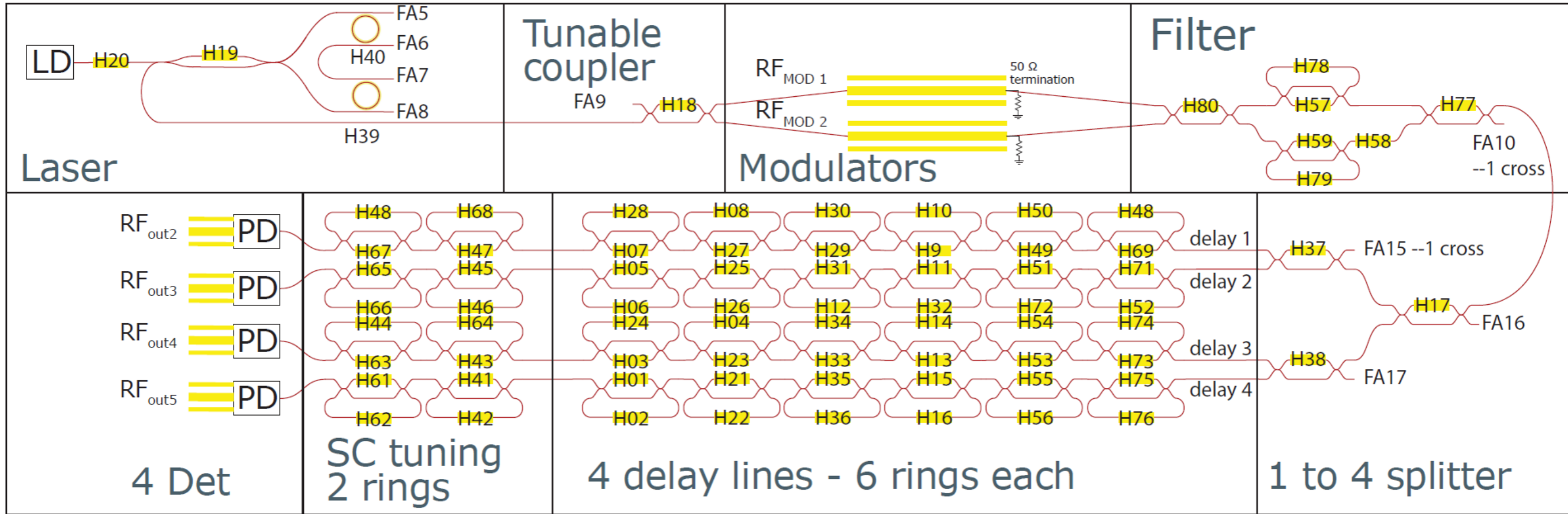
1 ns ~ 30 cm delay distance in vacuum

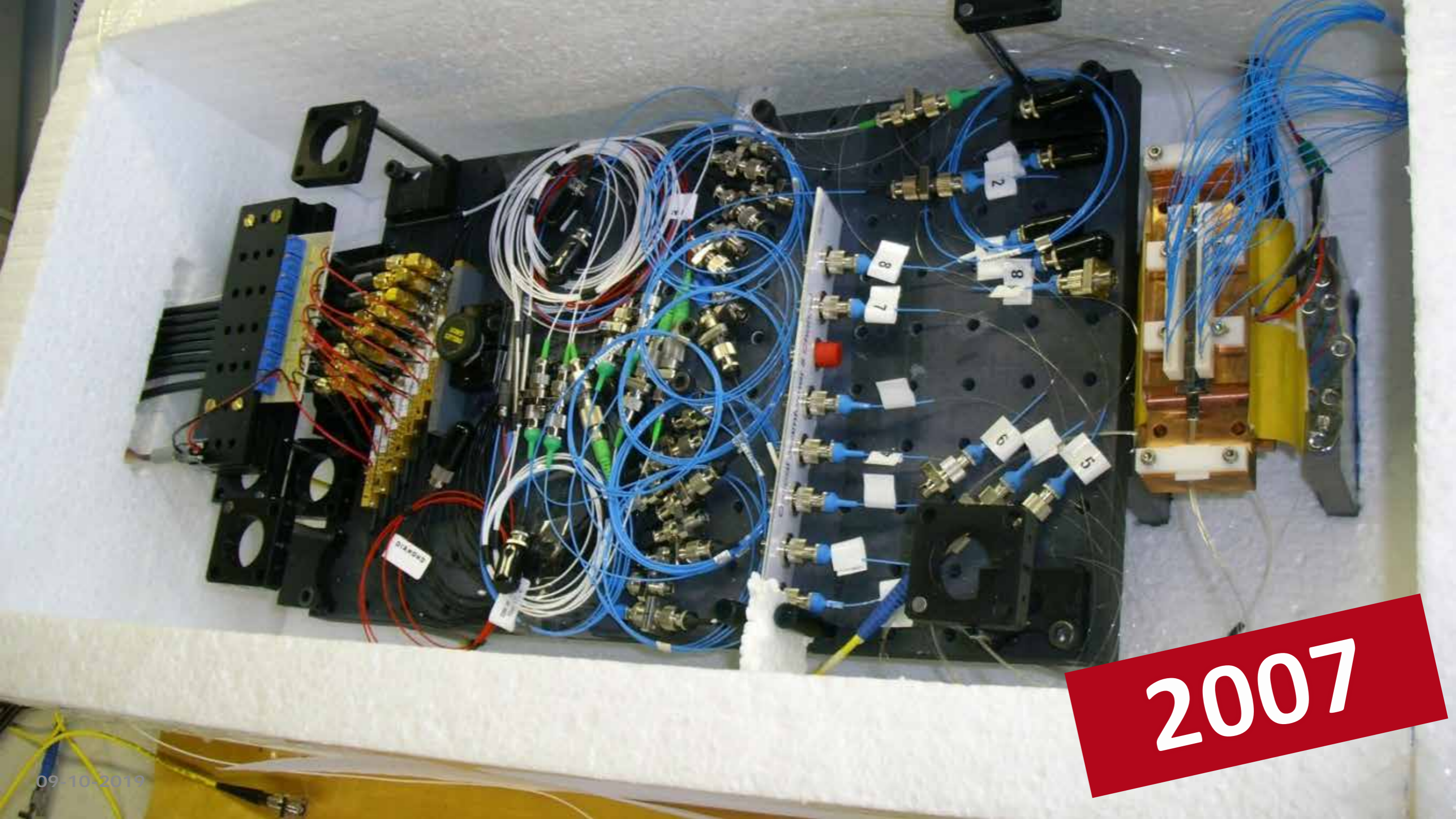


L. Zhuang et al.,

, vol. 19, no. 15, 2007

1xN Optical beamforming network





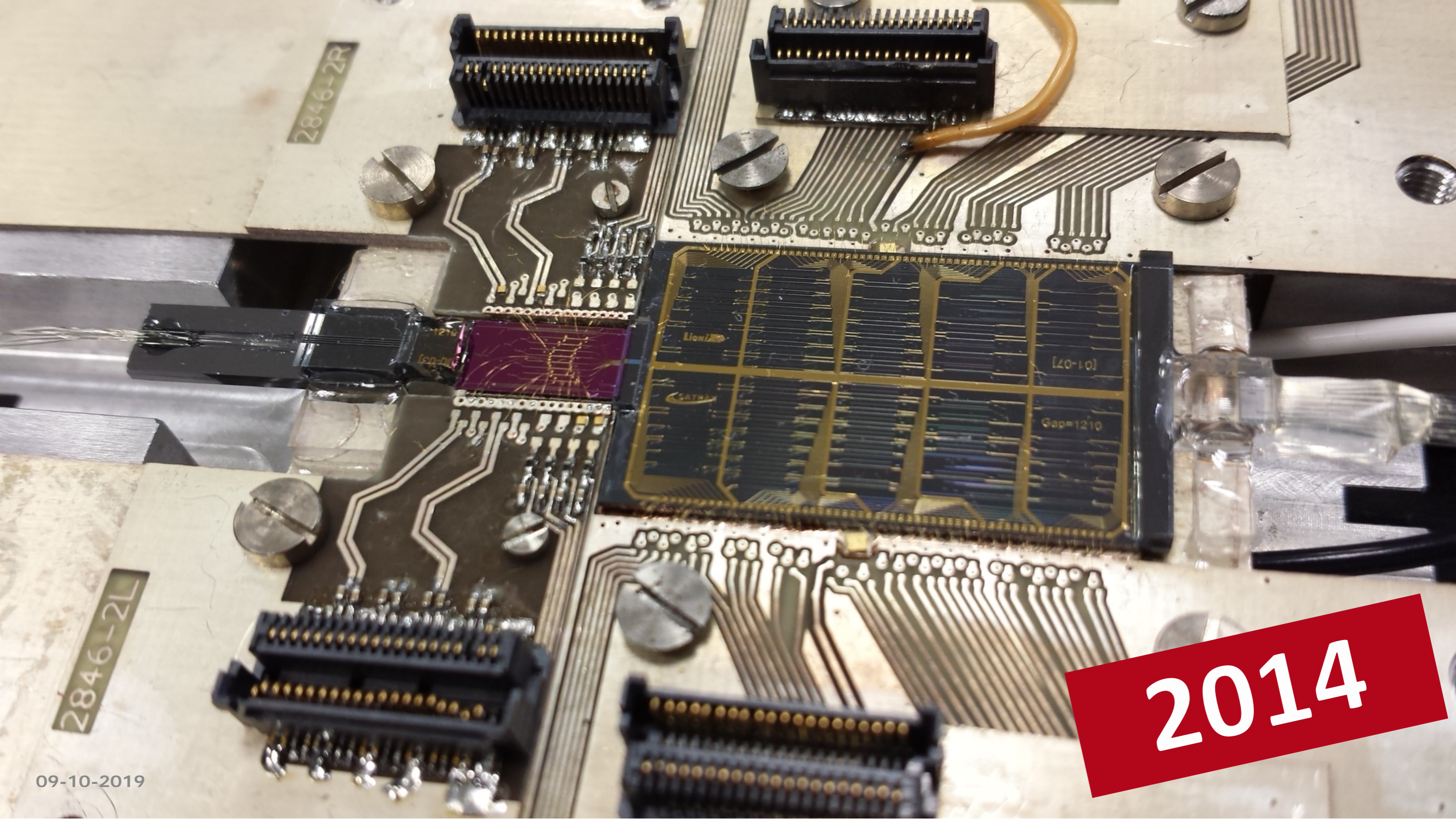
2007

2846-2R

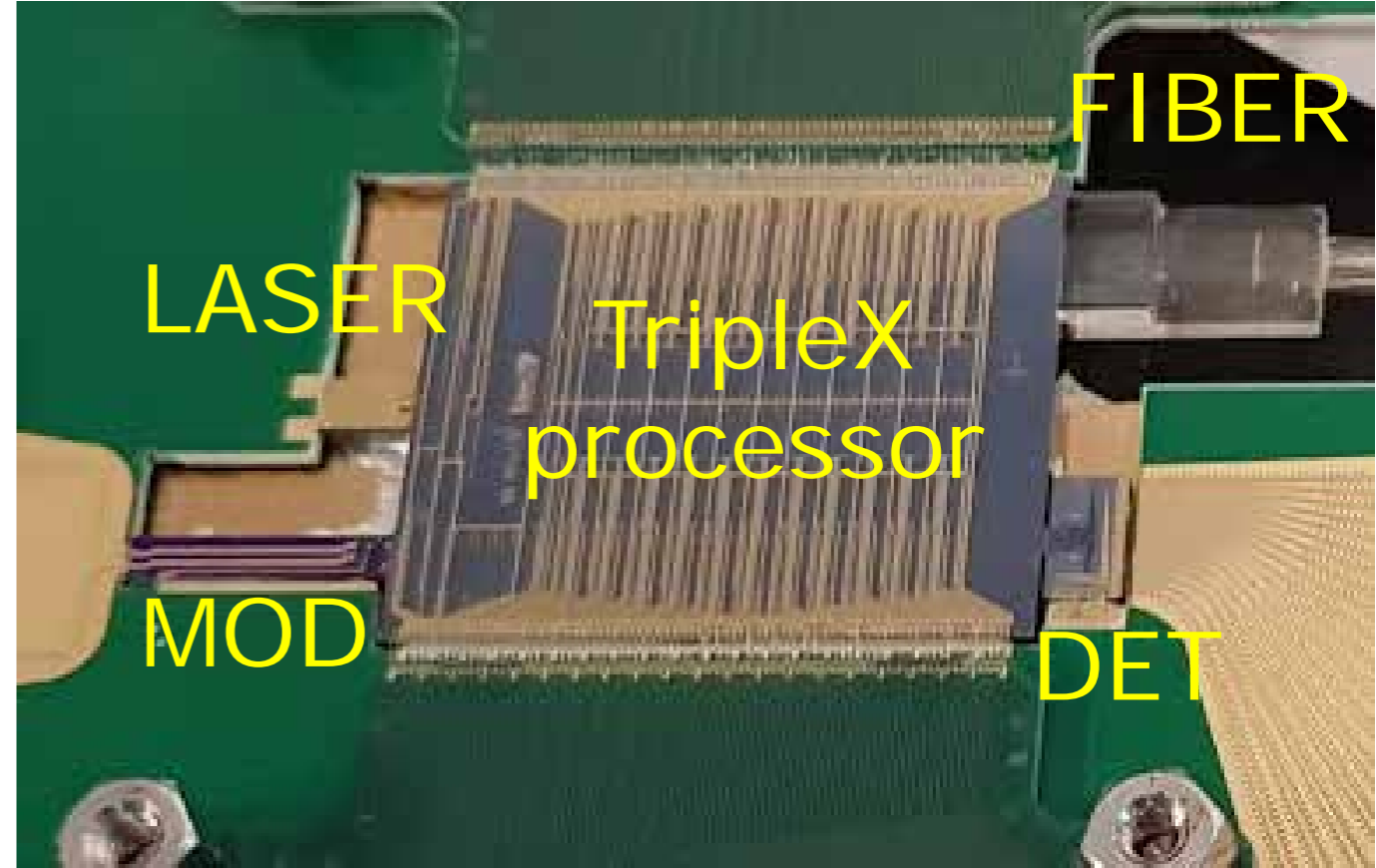
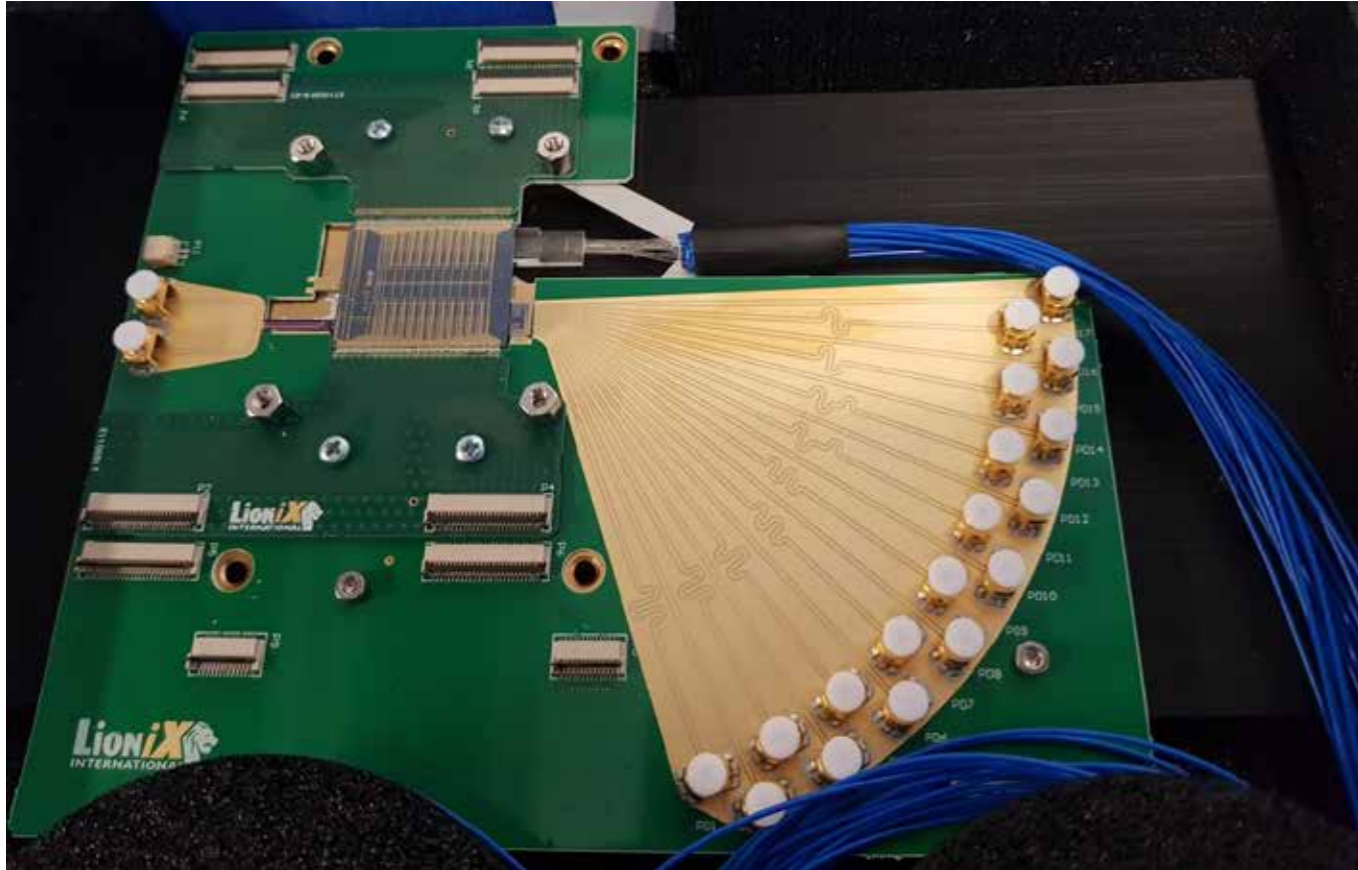
2846-2L

09-10-2019

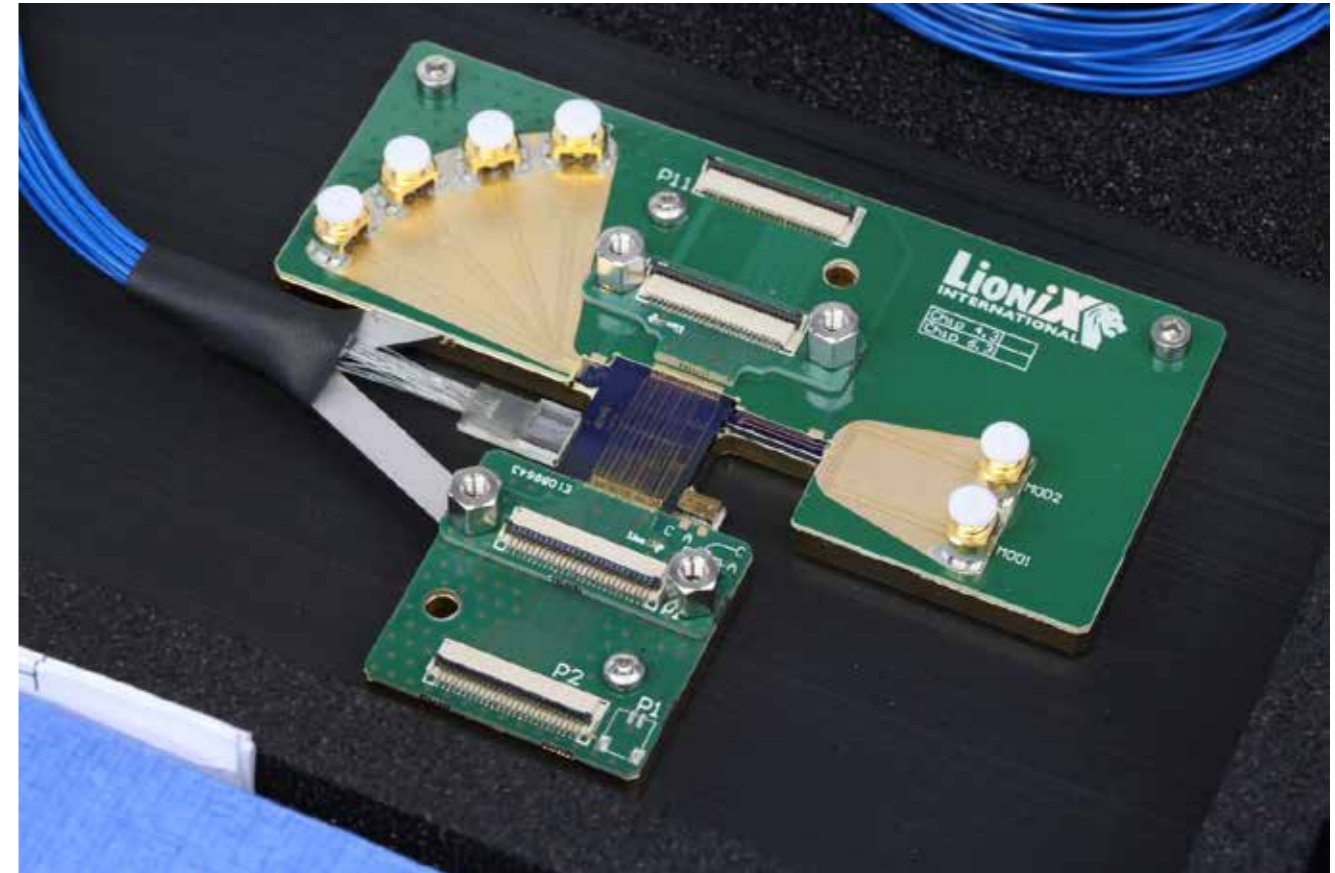
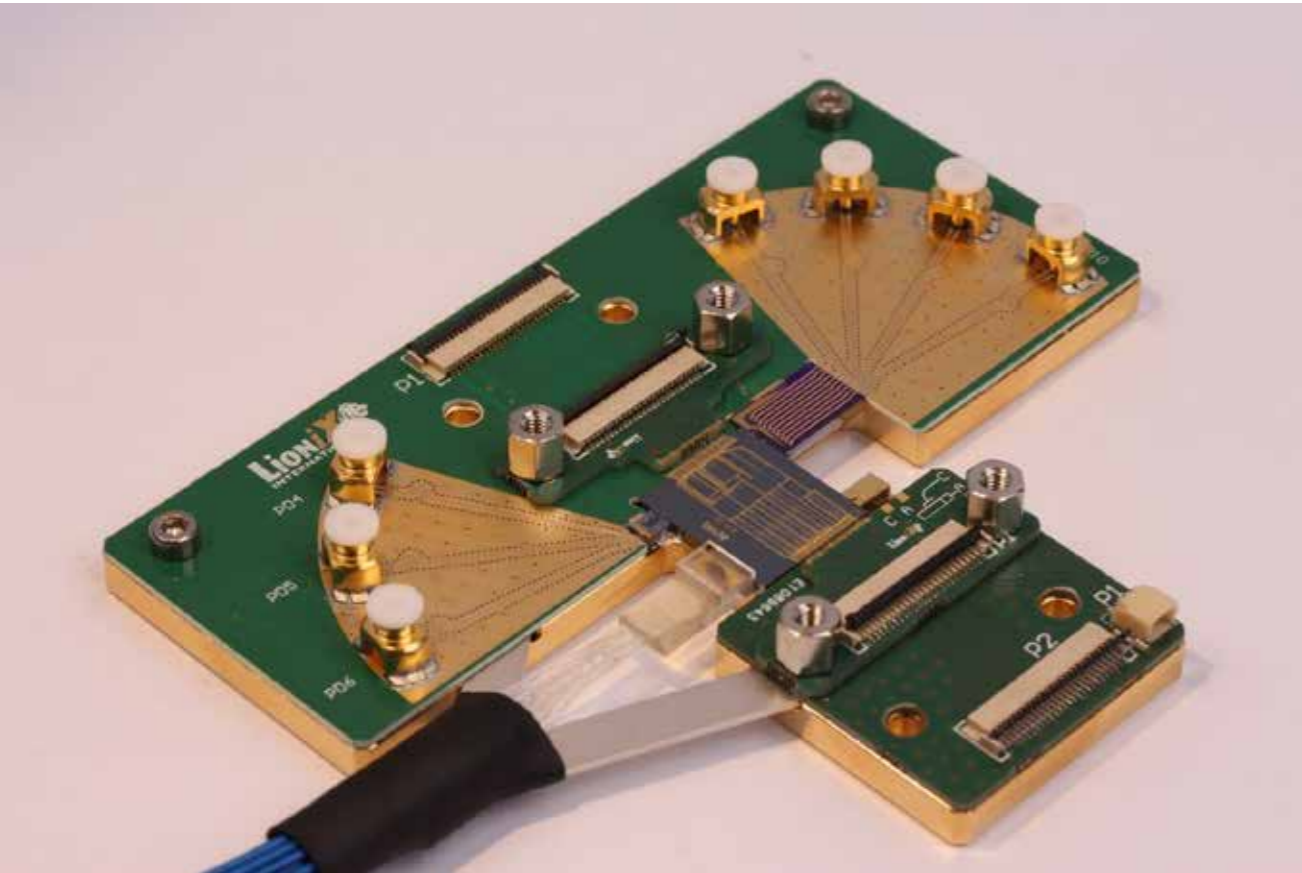
2014

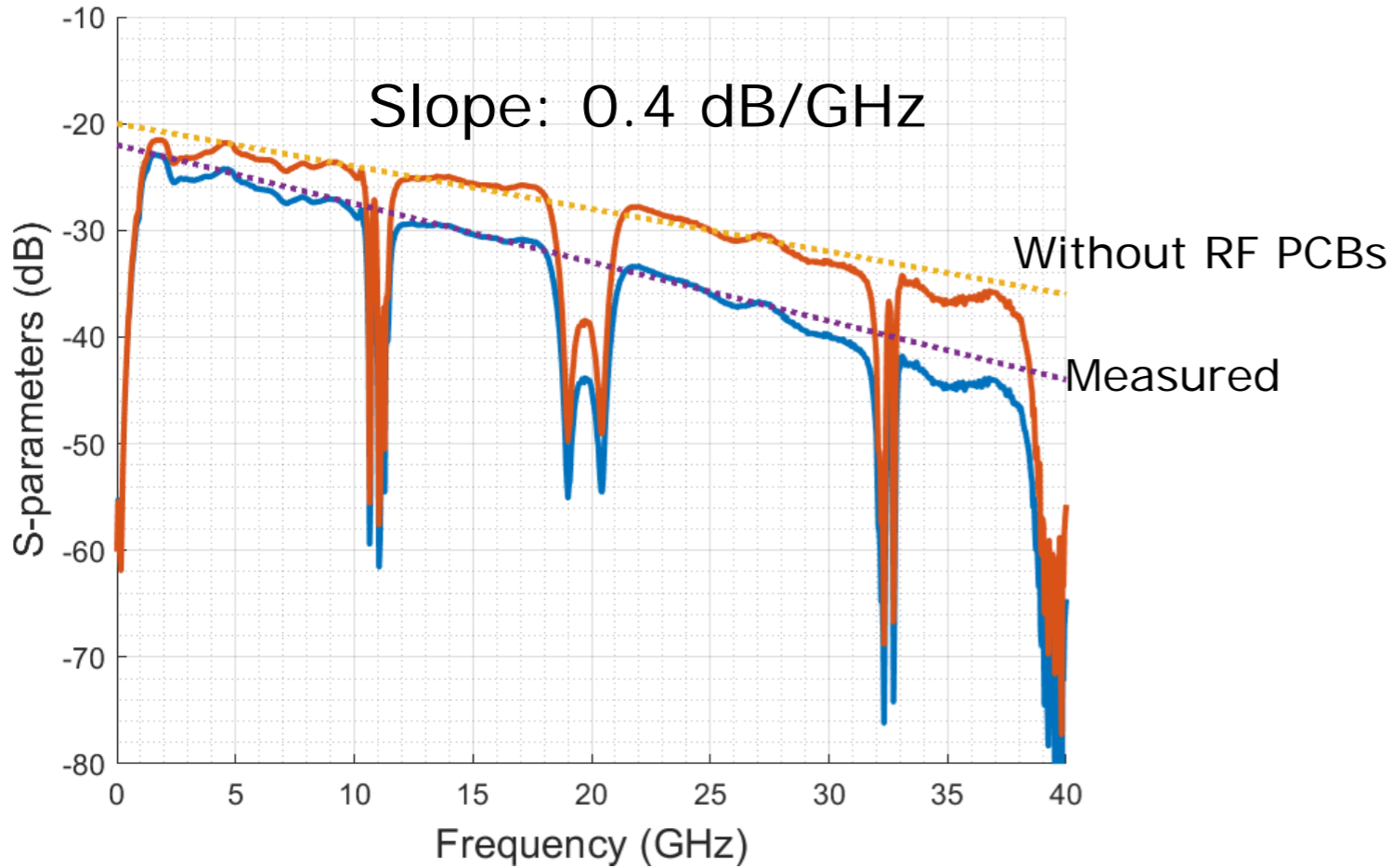


1xN Optical beamforming network



Breadboard Status





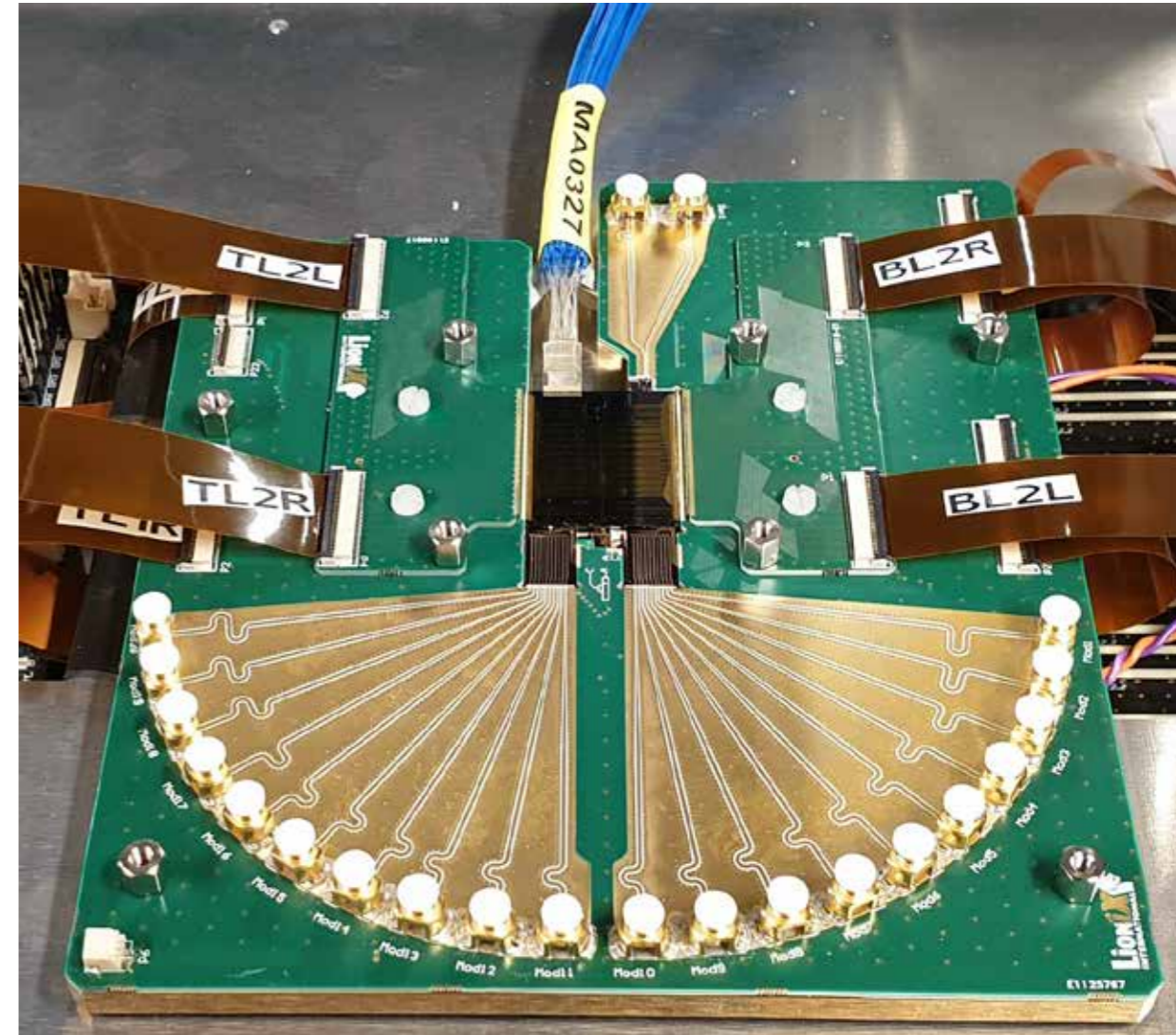
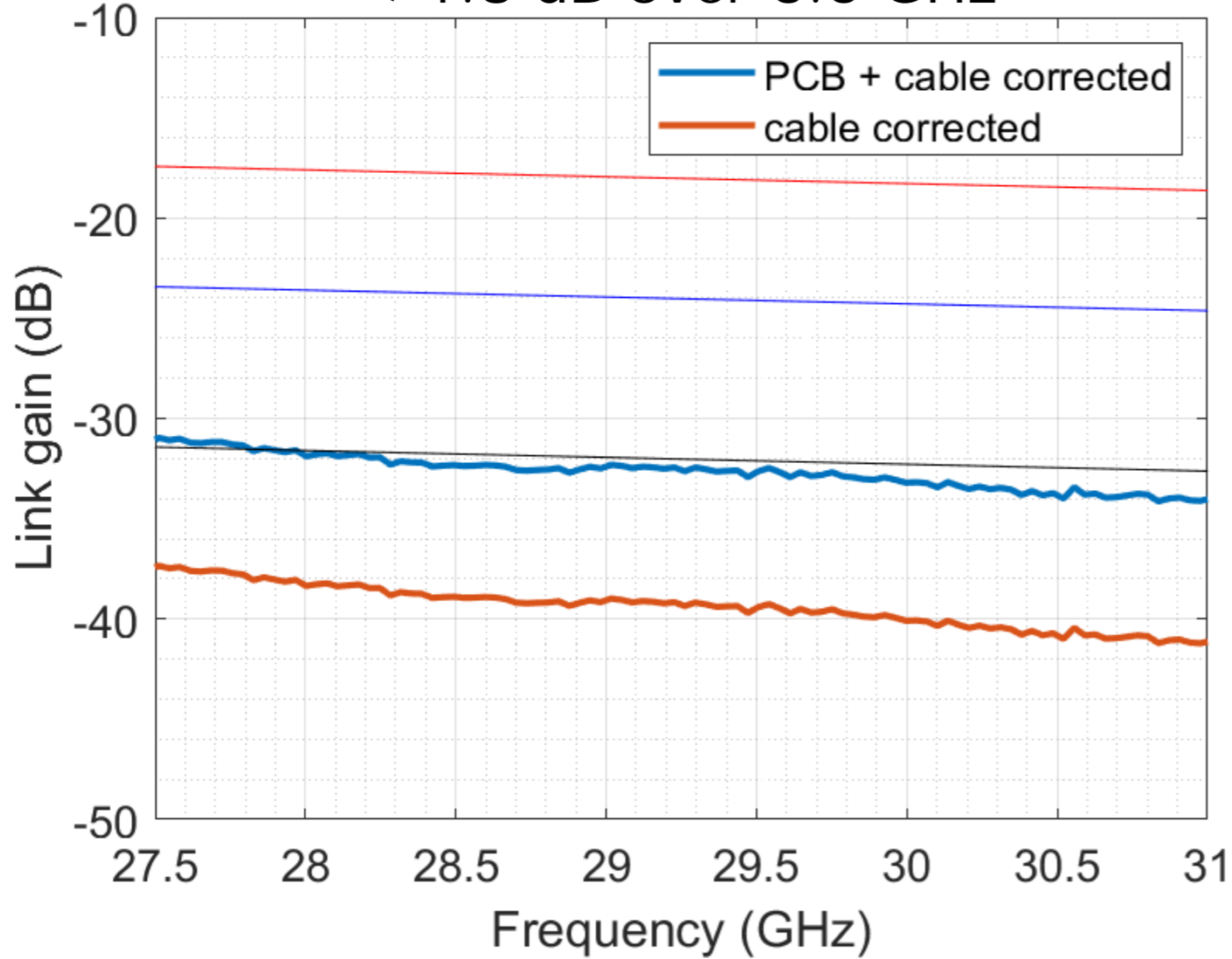
$$I_{PD_DC} = 3.8 \text{ mA}$$

	Freq (GHz)	G (dB)	V (V)
Measured	5	-22	4.0
	10	-24	4.7
	20	-28	7.7
	30	-32	11.8
Expected	30	-20	3
	20	-17.7	2.3

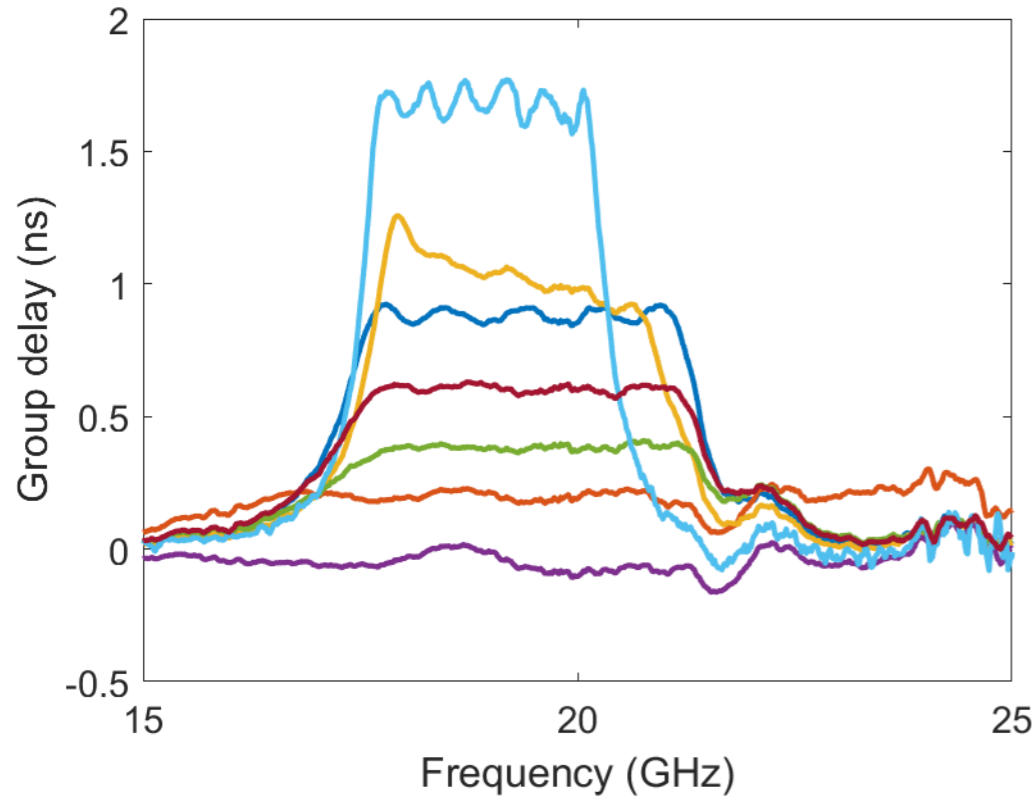
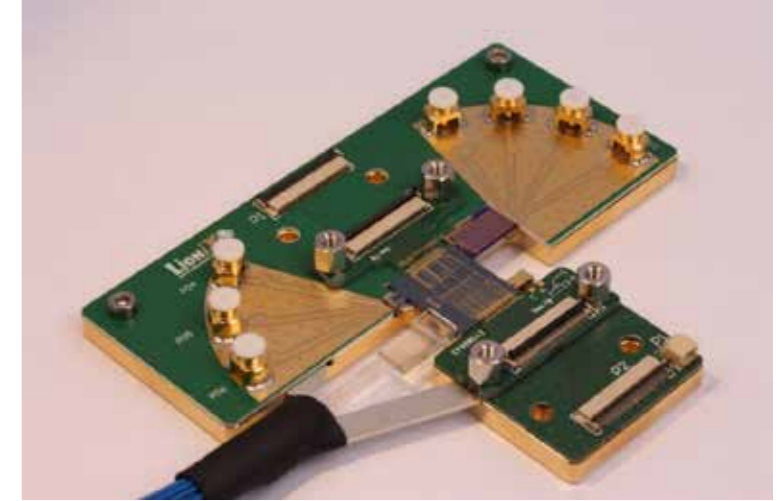
Reduced link gain is under investigation

Amplitude uniformity

< 1.8 dB over 3.5 GHz



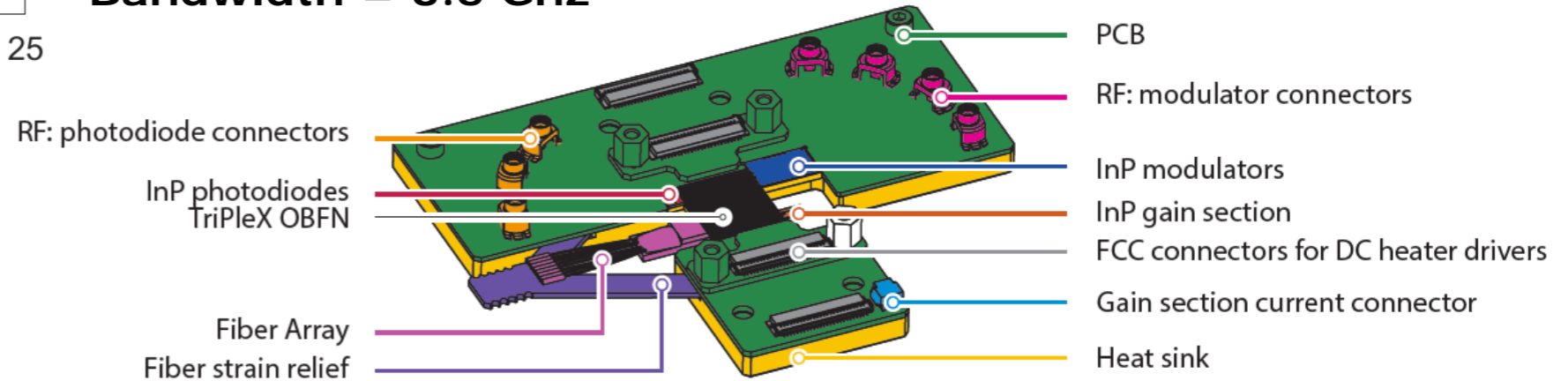
1x4 OBFN delay measurement

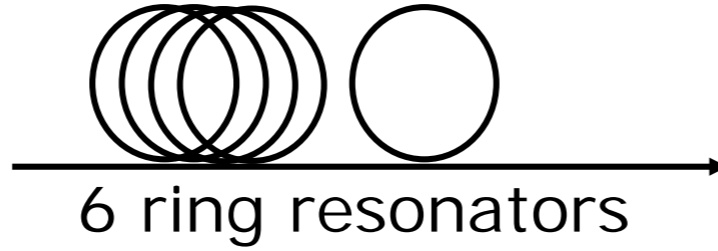


Light blue
 Delay = 1.8 ns
 Ripple = 100 ps
 Bandwidth = 2.5 GHz

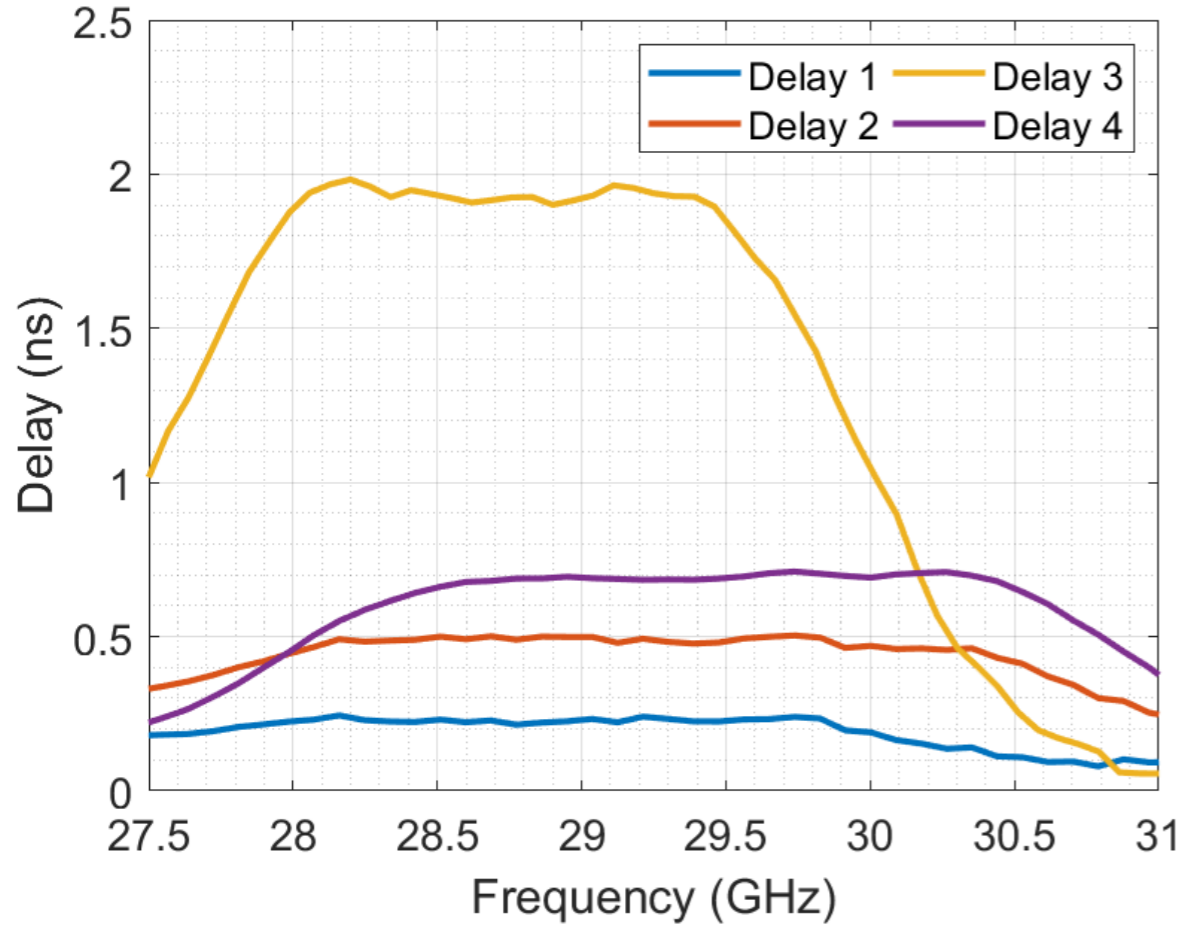
Yellow
 Dispersion compensation (via slope)

Other:
 Delay = 0-1 ns
 Maximum ripple = 50 ps
 Bandwidth = 3.5 GHz

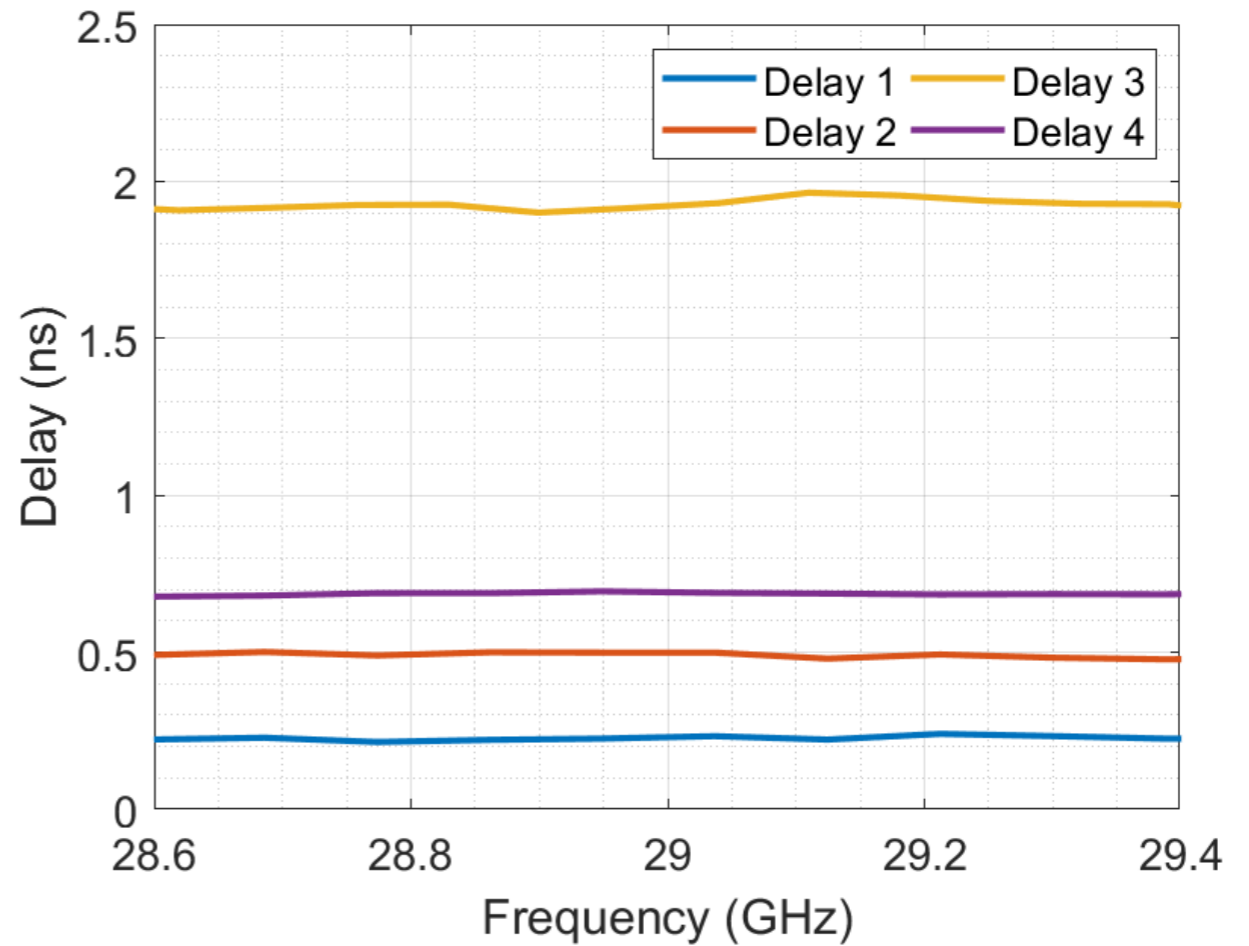




Tunable delays



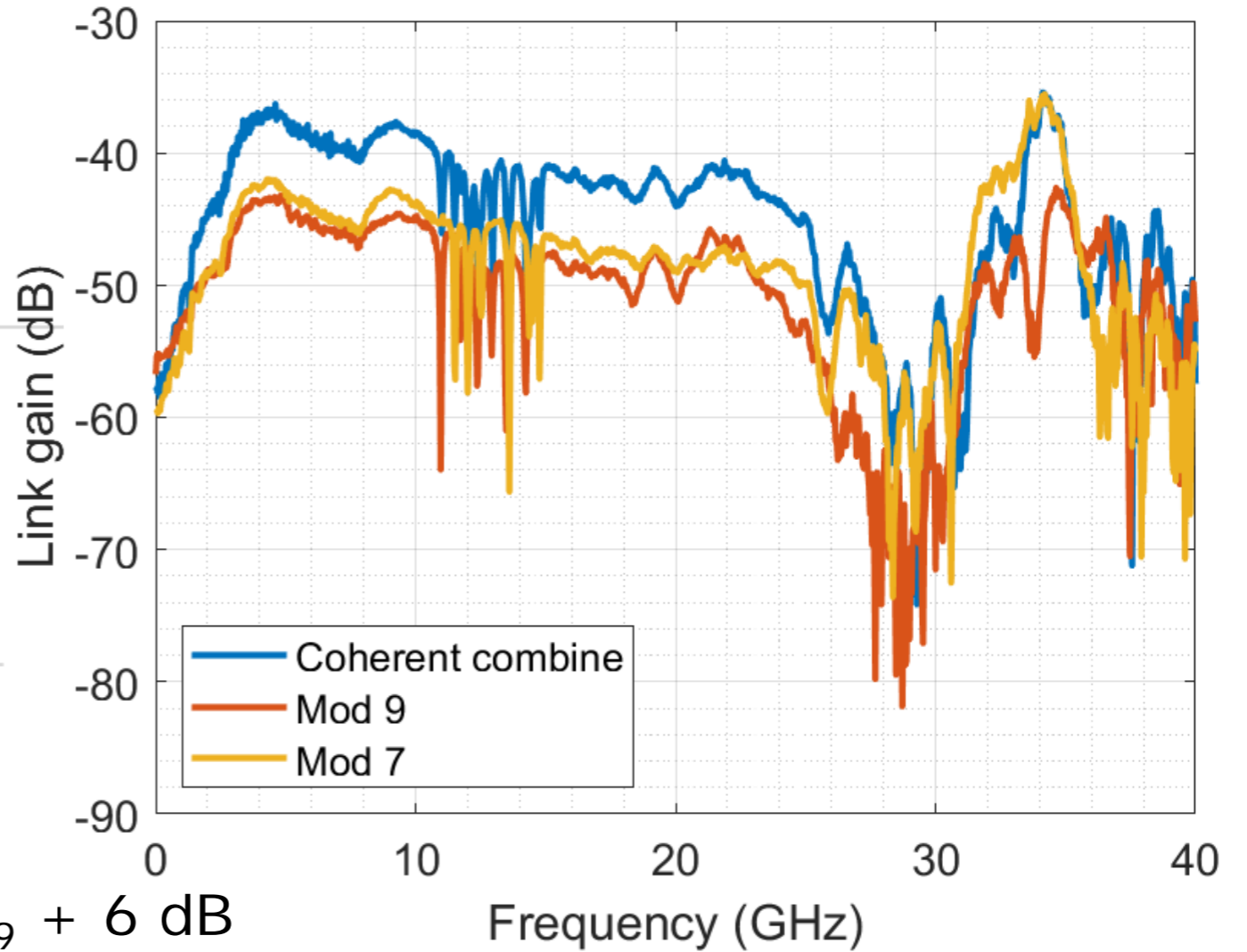
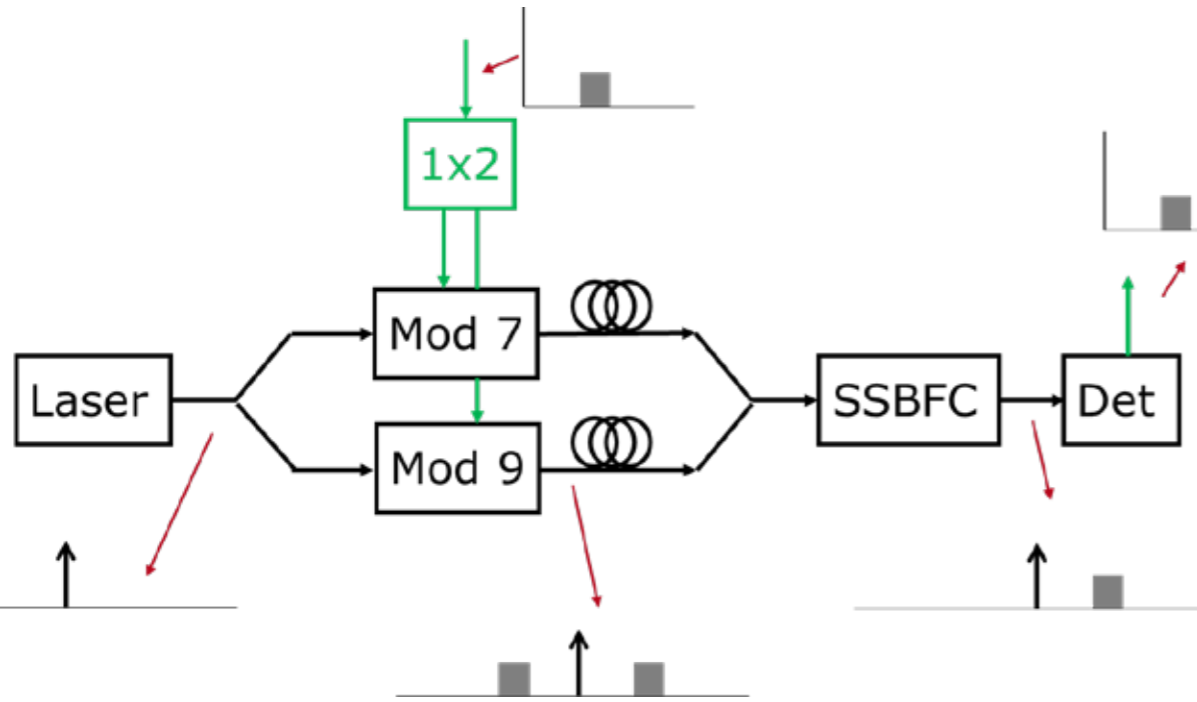
Tunable delay: 0 – 2 ns



Variation < 20 ps in 800 MHz

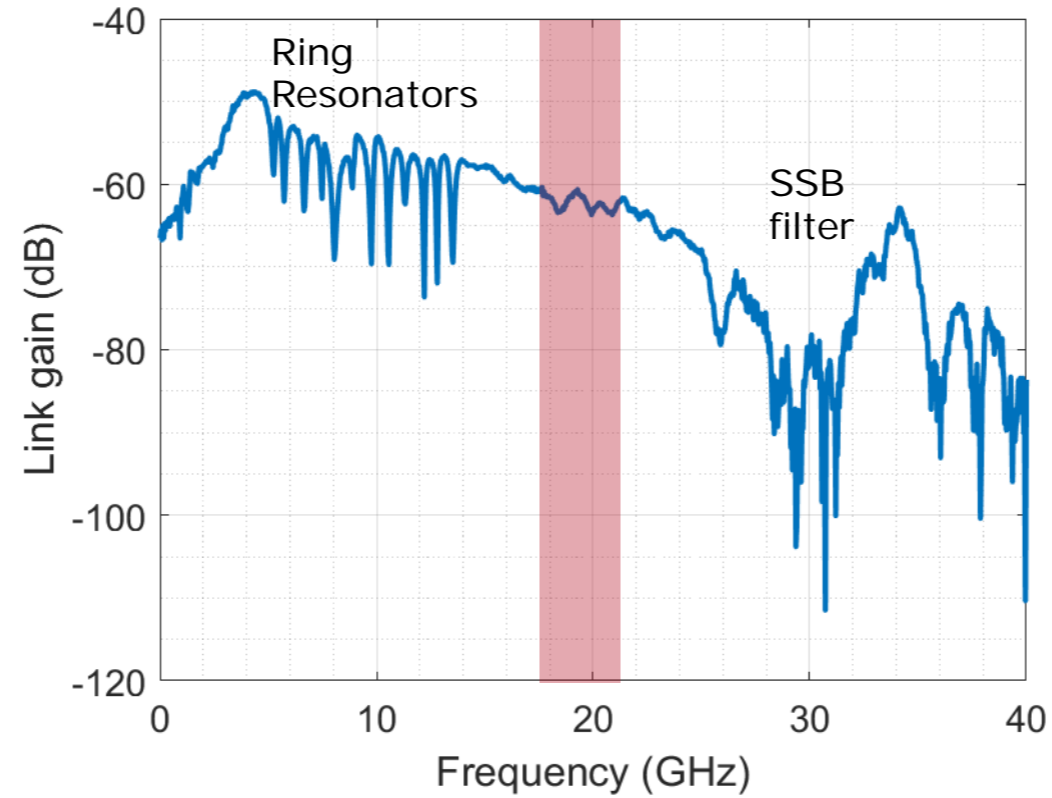
2x1 Coherent combining

I_{\max_PD}



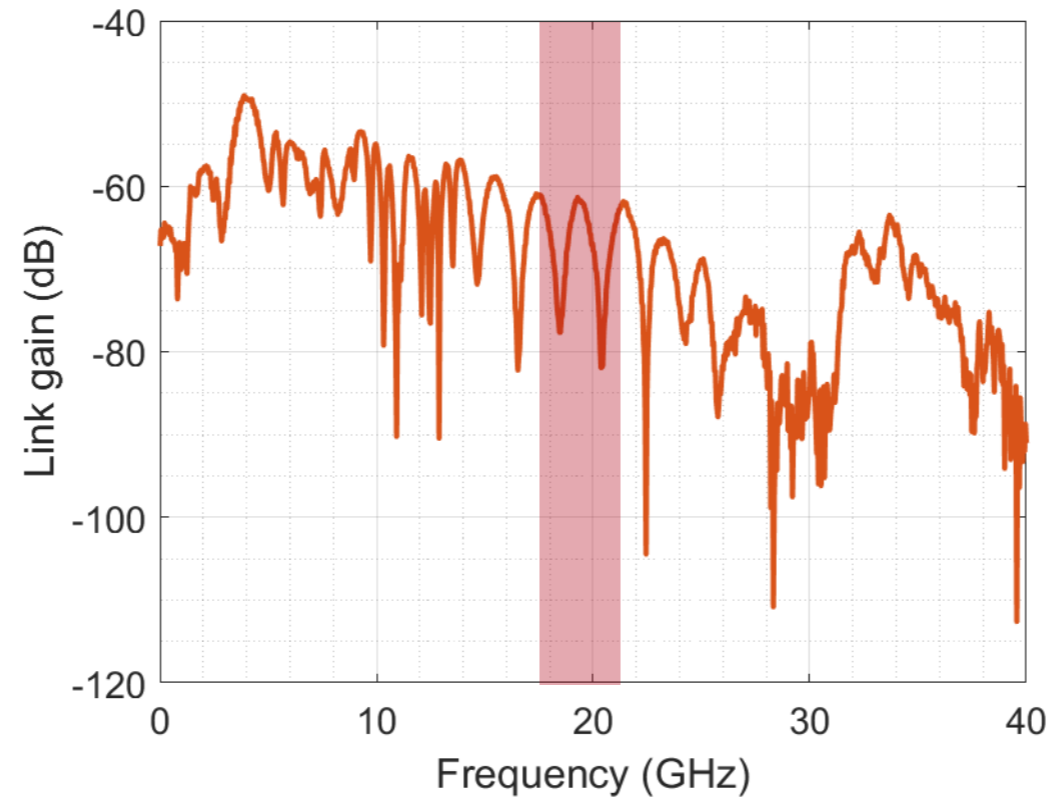
$$G_{\text{Coherent Combine}} = G_{\text{MOD 7}} + 6\text{dB} = G_{\text{MOD 9}} + 6\text{ dB}$$

- ~ No calibration
- ~ $I_{PD_Avg} = 0.5 \text{ mA}$



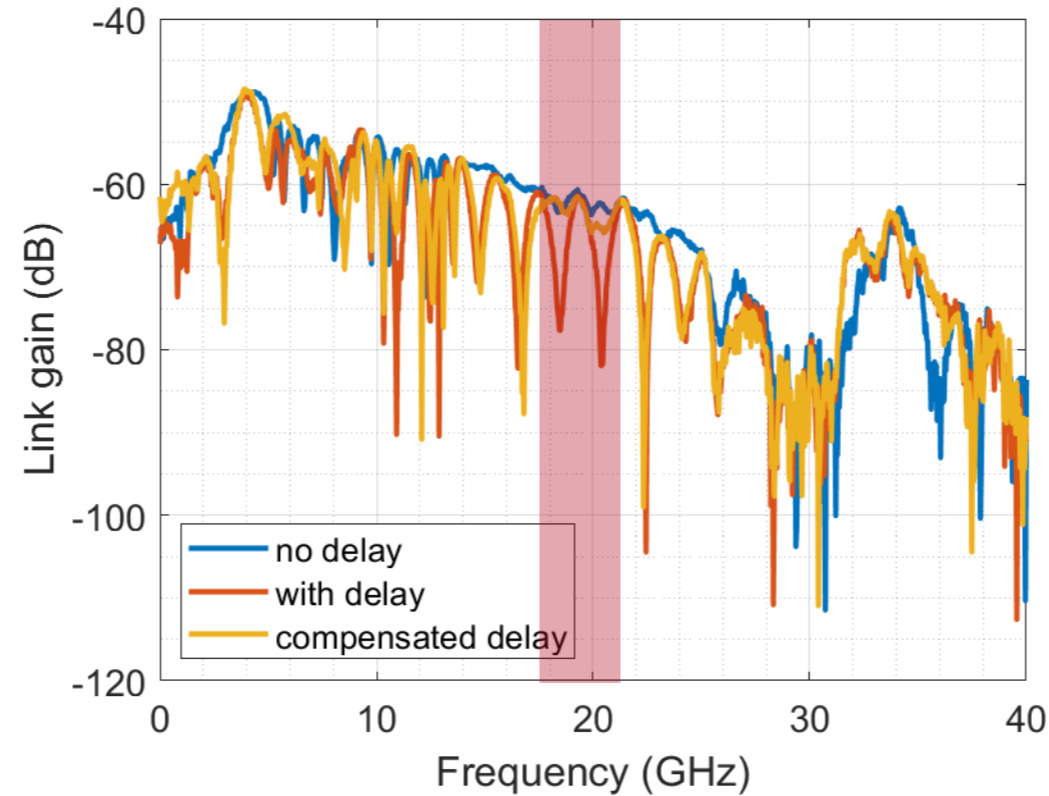
2x1 with 10 cm delay

- ~ No calibration
- ~ $I_{PD_Avg} = 0.5 \text{ mA}$
- ~ $f_{FSR} = 1.9 \text{ GHz}$

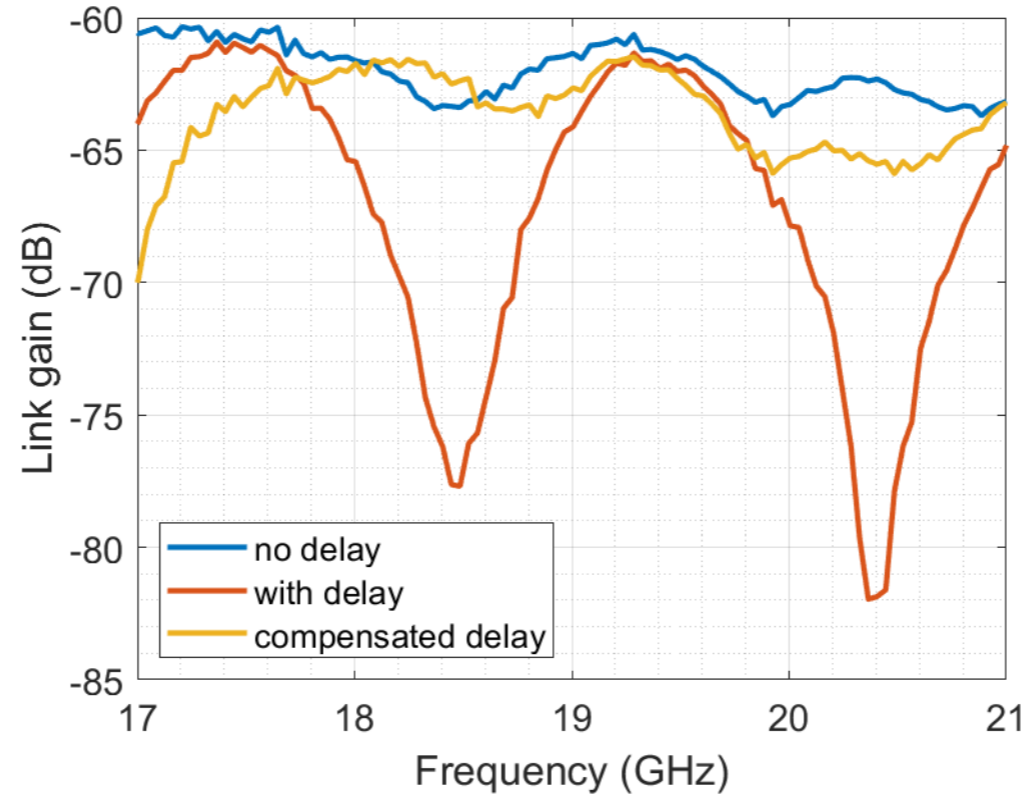


2x1 with delay compensation

- ~ 2 Ring resonators moved to signal band



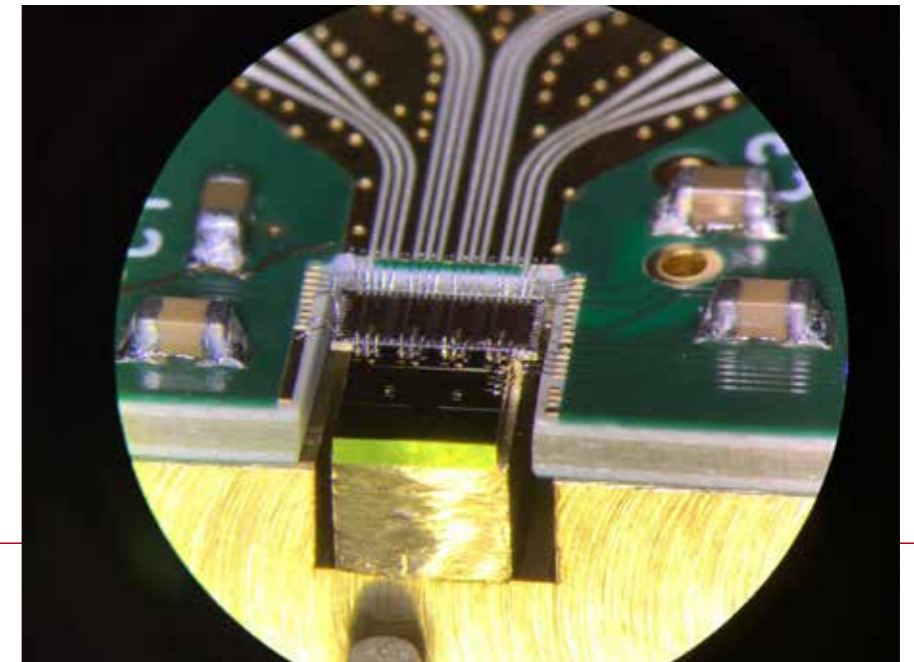
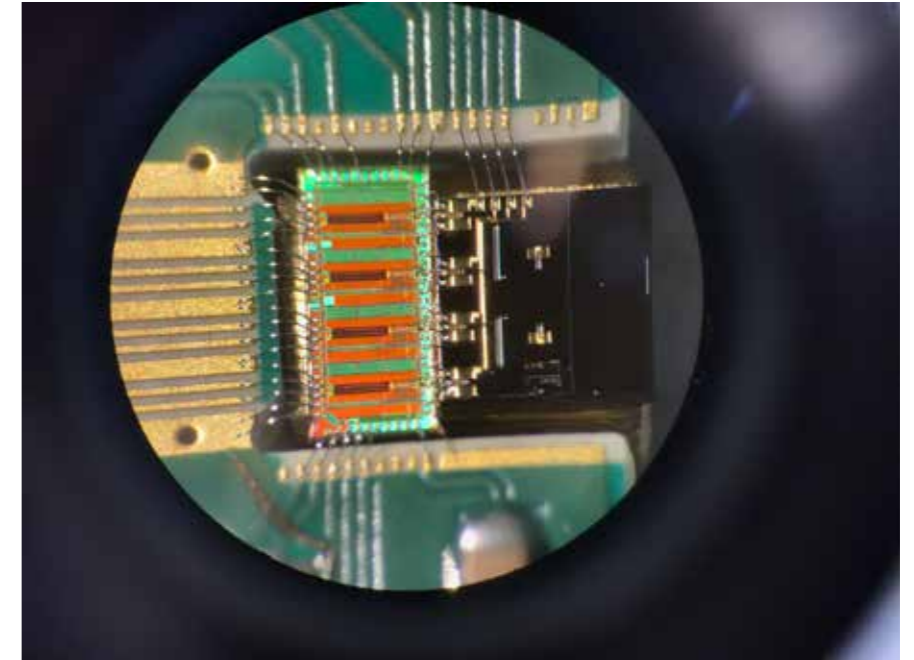
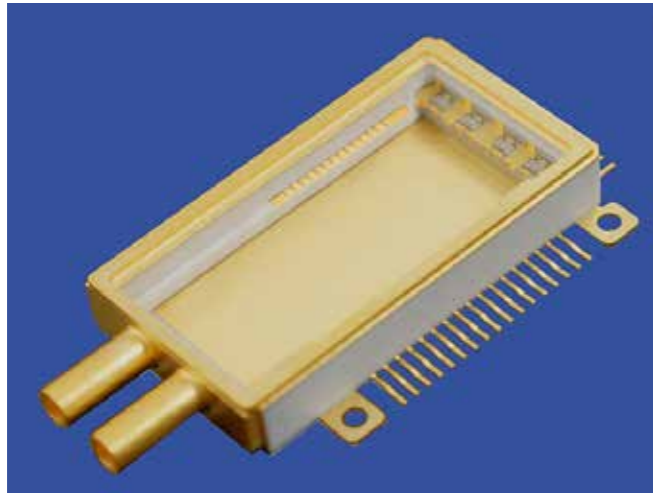
Zoom Ka Band



- ~ TriPleX™ quality is excellent resulting in low loss OBFN structures. The typical waveguide propagation losses are 0.05 dB/cm.
- ~ Laser performance is excellent with a laser power of 50 mW and RIN < -165 dB/Hz and there is an ability to further increase laser power to 100 mW.
- ~ Modulator performance is not according to specification, resulting in higher insertion loss. This issue can be solved by having a new InP Run
- ~ Detector performance is not according to specification, resulting in higher insertion loss of the MWP link. This issue can be solved by changing diode types with new InP run and.
- ~ Assembly procedures giving good results. Upscaling and improvement towards reproducibility and automation and production can continue to move forward. The fiber to chip coupling losses are 0.5 dB and the InP to TripleX coupling losses are 1 - 1.5 dB.
- ~ The OBFNs are operating as expected. Phase, delay and amplitude can be controlled independently for each path
- ~ The system is time stable. Settings did not change over the period of testing (days to weeks).
- ~ Broadband microwave beamforming has been achieved using photonics.

Future improvements

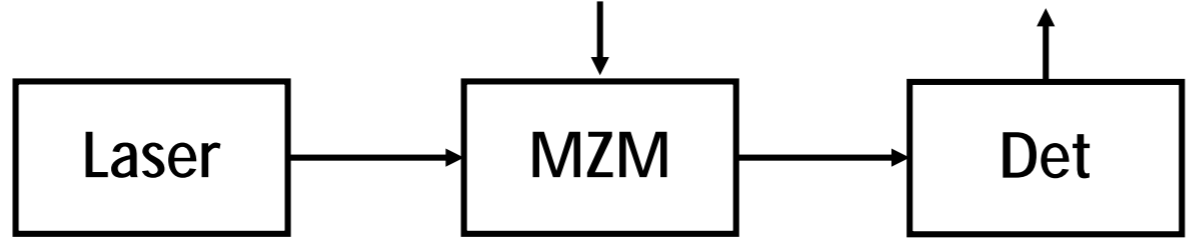
- ~ Miniturise (package design)
- ~ Integrate more electronics
- ~ Use trans impedance amplifiers
- ~ Scale up (develop assembly procedures)
- ~ Improve Active components



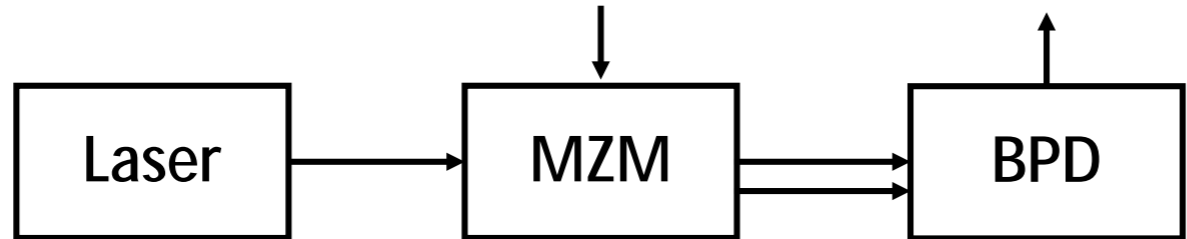


AOL Cases

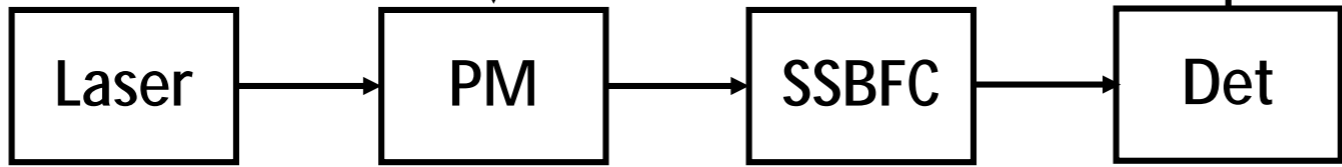
MZM - DD



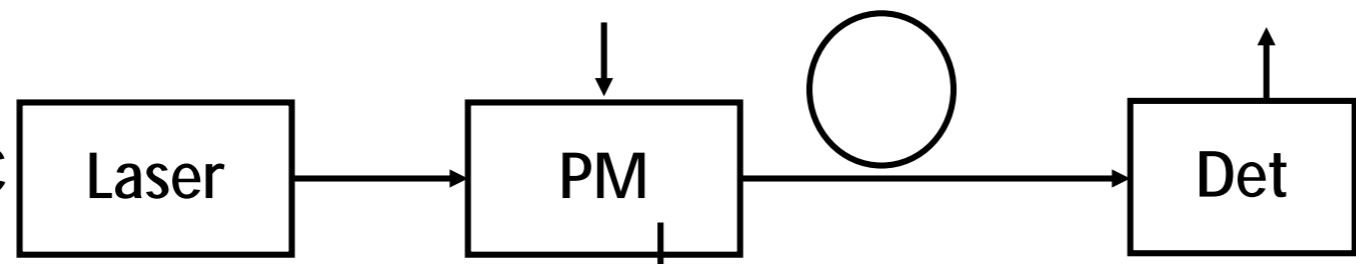
MZM - BPD



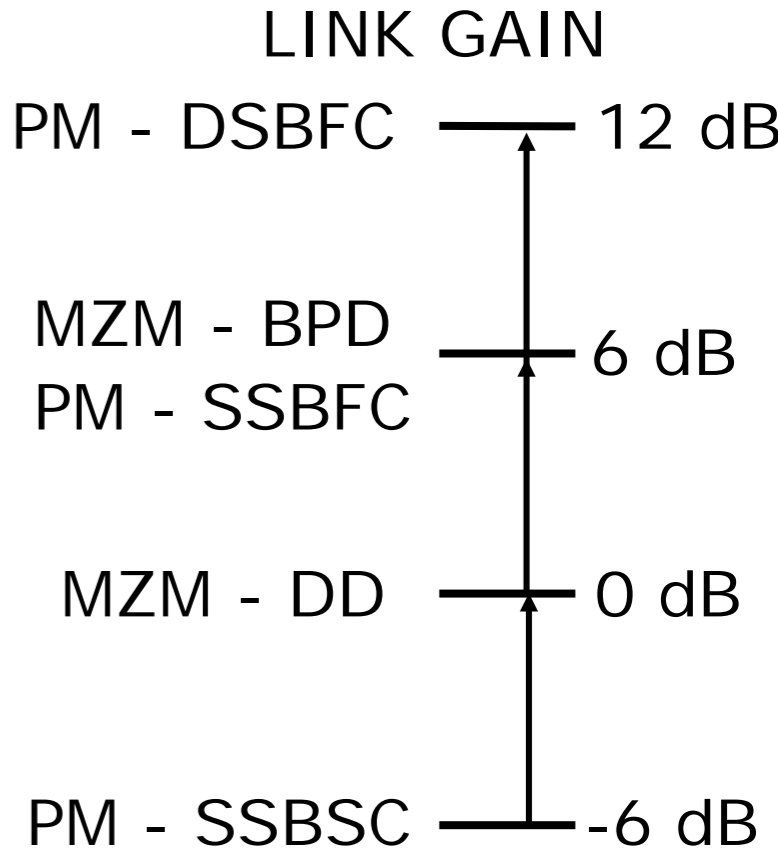
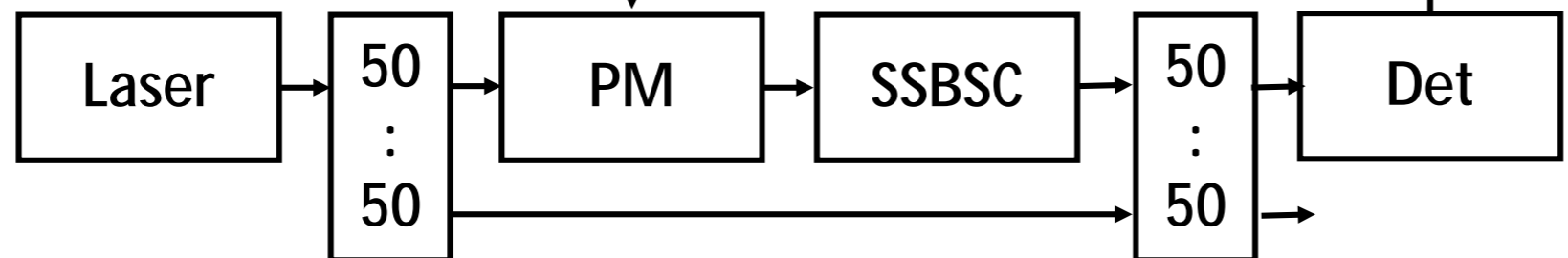
PM - SSBFC



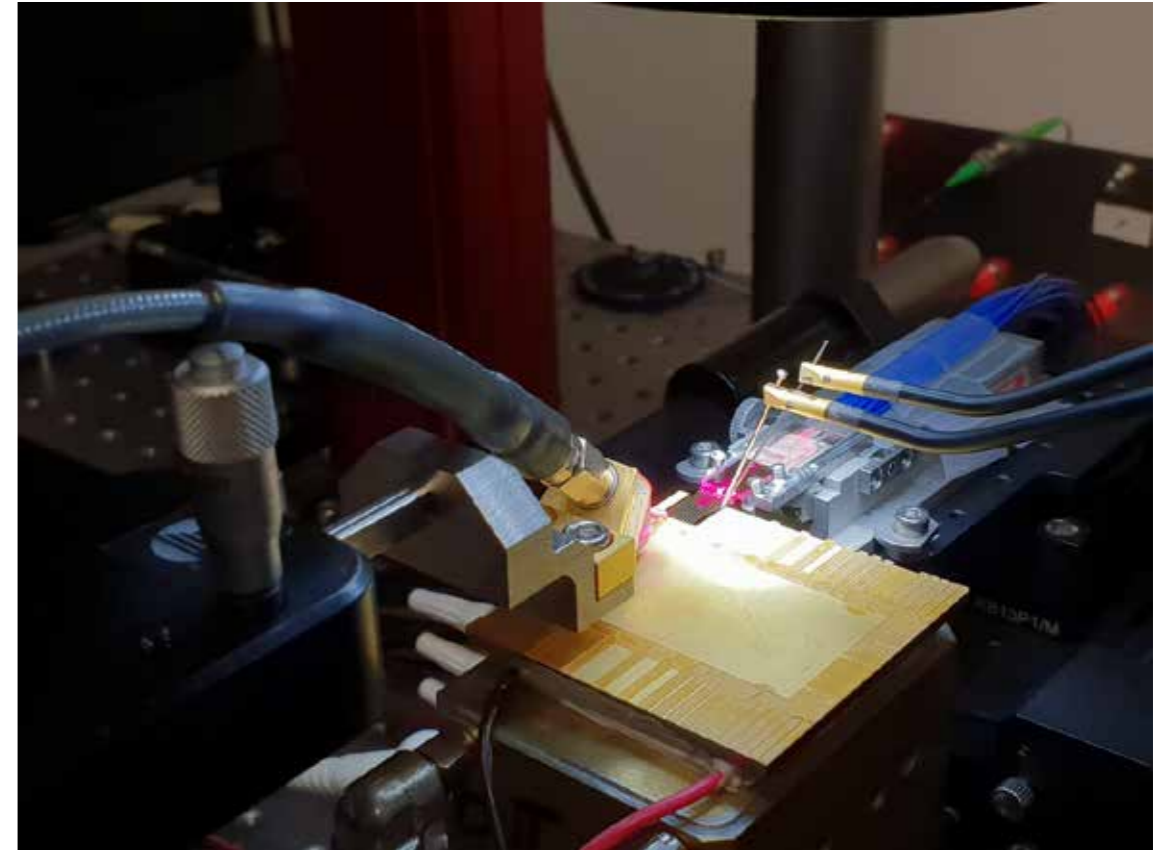
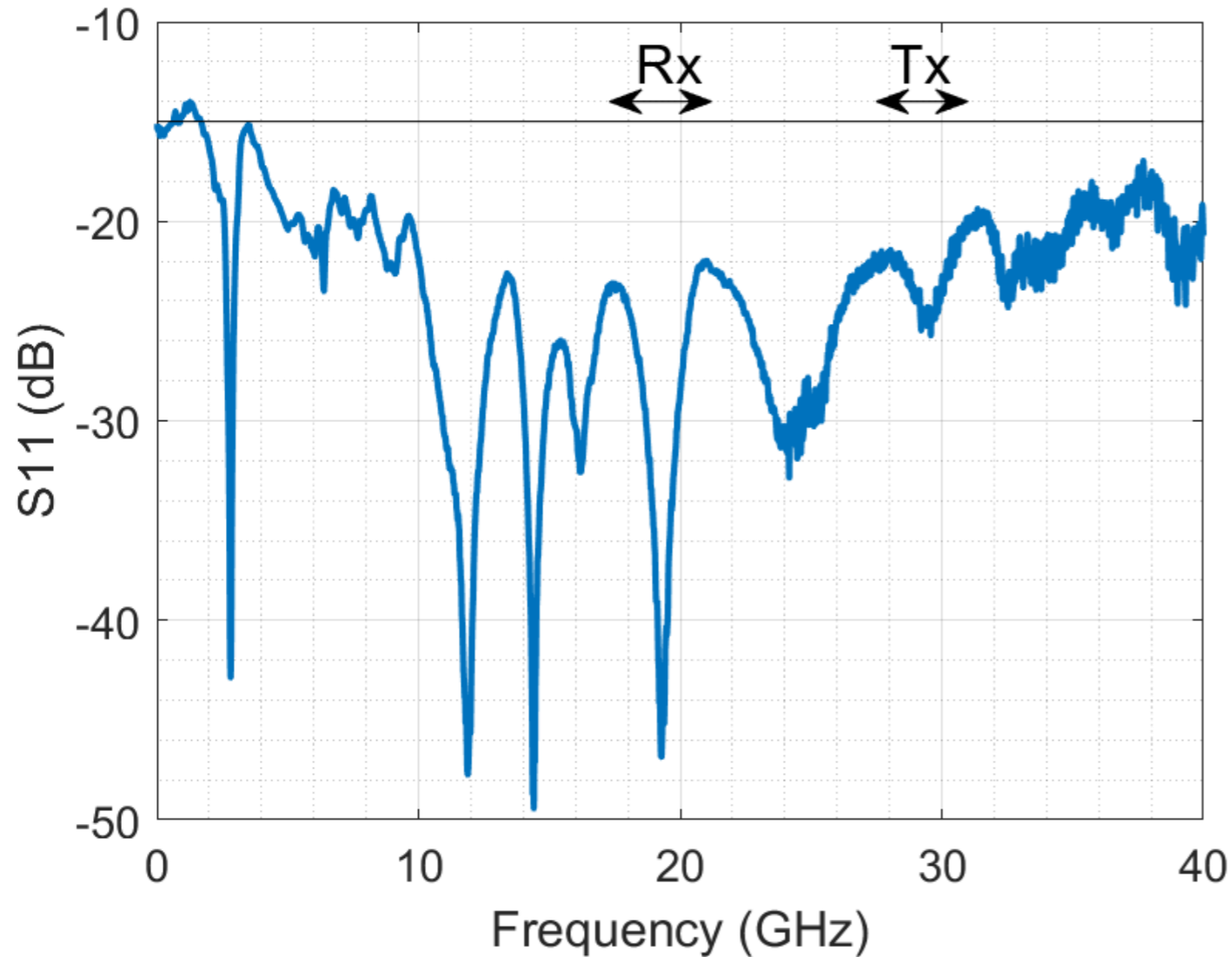
PM - DSBFC



PM - SSBSC

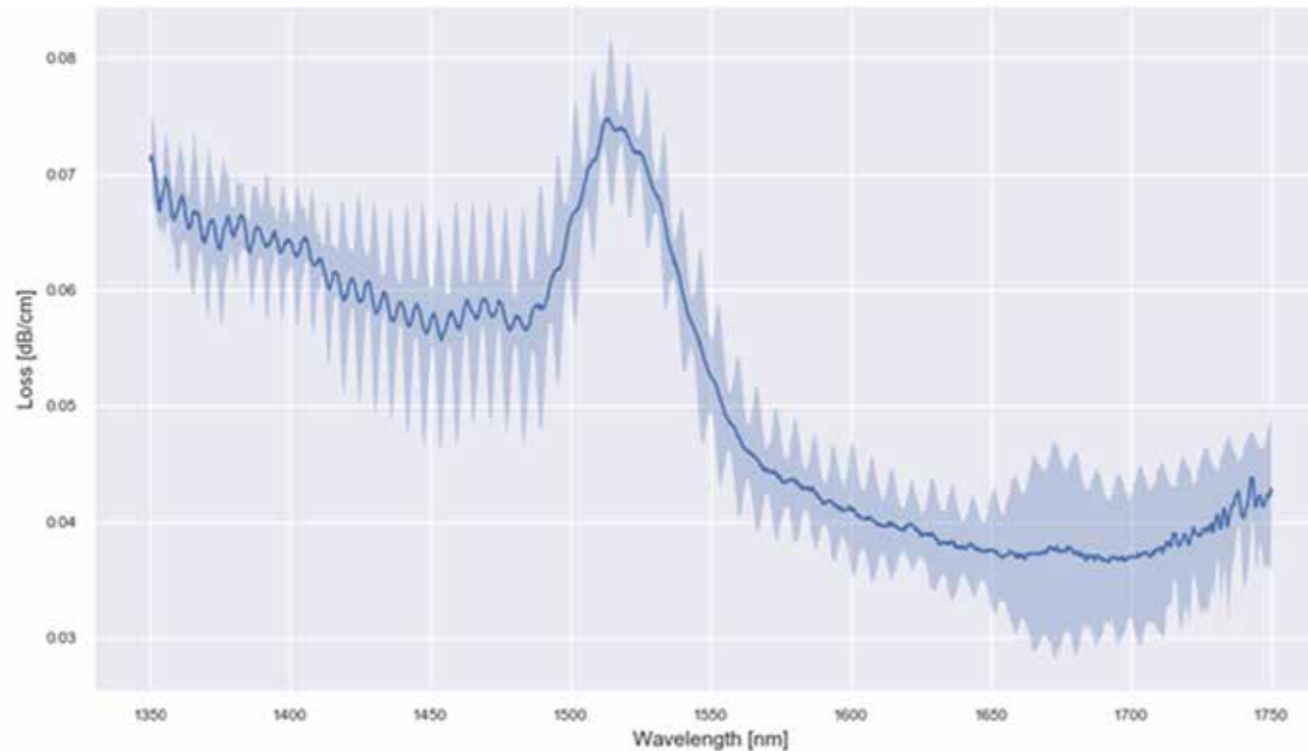


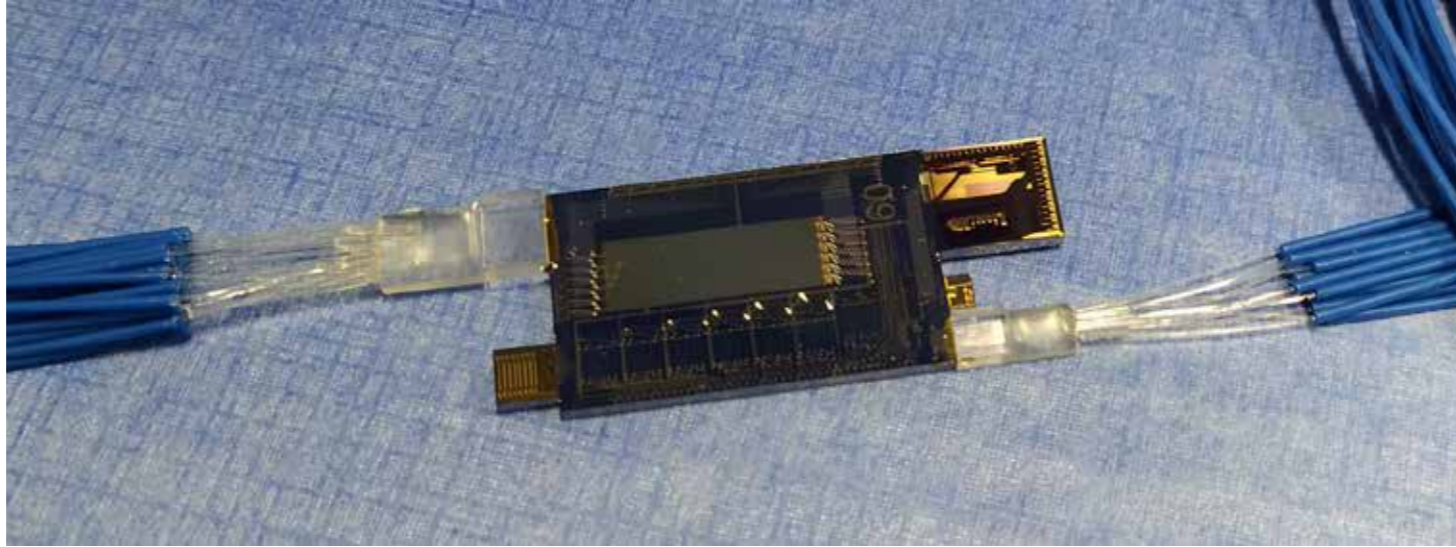
Modulator Return Loss



Measurement setup: VNA

- ~ ADS PZT compatible waveguide loss measurement (< 0.1 dB/cm)
- ~ **Total** detector measured)





PZT